







ZHCSLK7A - JULY 2020 - REVISED APRIL 2023





BQ21062 具有电源路径、负载开关、10nA 运输模式和稳压系统 (PMID) 电压的 I²C 控制型单节电池 500mA 线性电池充电器

1 特性

- 具有 1.25mA 至 500mA 快速充电电流范围的线性 电池充电器
 - 0.5% 精度 I²C 可编程电池稳压电压,范围为 3.6V 至 4.6V 且阶跃为 10mV
 - 可配置的终止电流,支持低至 0.5mA
 - 可耐受 20V 的输入, 具有 3.4V 至 5.5V 的典型 输入电压工作范围
 - 可编程热负荷曲线,完全可配置的热、温、凉、 冷阈值
- 电源路径管理,用于系统供电和电池充电
 - I²C 可编程稳定系统电压 (PMID) 范围为 4.4V 至 4.9V,此外还具有电池电压跟踪功能和输入直通
 - 动态电源路径管理可以对通过弱适配器充电进行
 - 利用高级 I²C 控制, 主机可以根据需要断开电池 或适配器
- I²C 可配置负载开关或高达 150mA LDO 输出
 - 可编程范围为 0.6V 至 3.7V, 阶跃为 100mV
- 超低 Iddq,可延长电池寿命
 - 10nA 运输模式电池 Iq
 - 在为系统供电时具有 400nA 的 lq (PMID 和 VDD 打开)
- 通过可调节计时器实现单按钮唤醒和重置输入
 - 支持系统循环通电和硬件重置
- 20 引脚 2mm x 1.6mm CSP 封装
- 总解决方案尺寸为 11mm²

2 应用

- 耳麦、耳塞和助听器
- 智能手表和智能追踪器
- 可穿戴健身和活动监测仪
- 血糖监测仪

3 说明

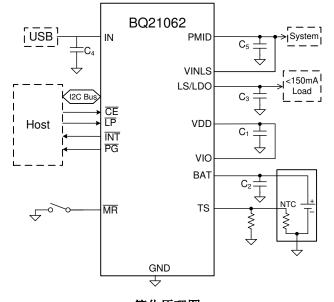
BQ21062 是一款高度集成的电池充电管理 IC, 其集成 了适用于可穿戴设备、便携式设备和小型医疗设备的常 用功能,即充电器、用于系统电源的稳定输出电压轨、 负载开关/LDO 以及按钮控制器。

BQ21062 IC 集成了具有电源路径的线性充电器,可实 现对小型电池进行快速准确的充电,同时为系统提供稳 定电压。根据下游 IC 和系统负载的建议运行条件,稳 定系统电压 (PMID) 输出可通过 I²C 进行配置,从而实 现最佳的系统运行。

器件信息(1)

器件型号	封装	封装尺寸(标称值)		
BQ21062	DSBGA (20)	2.00mm x 1.60mm		

如需了解所有可用封装,请参阅数据表末尾的可订购产品附 录。



简化原理图



Table of Contents

29
32
53
53
5 3
58
59
59
59
60
60
60
60
60
60
60
60
61

4 Revision History 注:以前版本的页码可能与当前版本的页码不同

Changes from Revision * (July 2020) to Revision A (April 2023)	Page
Changed t _{HW RESET WD} Test Conditions and MAX value	10
Changed t _{RESET_WARN}	10
Changed t _{HW_RESET}	
• Changed 图 9-3	20
• Changed t _{HW_RESET_WARN} to t _{RESET_WARN} in 节 9.3.7.2	
• Changed VIN presence to valid VIN presence in 节 9.3.7.2	
• Changed text in 节 9.4.1	29



5 说明(续)

该器件支持高达 500mA 的充电电流,并且支持低至 0.5mA 的终止电流,以实现最充分的充电。该器件采用标准 锂离子充电曲线分三个阶段对电池进行充电:预充电、恒流和恒压调节。

该器件集成了高级电源路径管理和控制,使该器件可以为系统提供电源,同时甚至能够使用很差的适配器为电池充电。主机还可以通过 I²C 控制电源路径,允许它断开输入适配器和/或电池,而无需实际移除它们。单按钮输入无需单独的按钮控制器 IC,从而减少了整体解决方案占用空间。按钮输入可用于唤醒功能或重置系统。运行和关断期间的低静态电流有助于延长电池寿命。可通过 I²C 接口对输入电流限制、充电电流、LDO 输出电压和其他参数进行编程,从而使 BQ21062 成为非常灵活的充电解决方案。该器件包含一个基于电压的 JEITA 兼容(或标准热/冷)电池组热敏电阻监控输入 (TS),可监控电池温度并自动更改充电参数,从而防止电池在超出其安全温度范围的温度下充电。还可以通过 I²C 对温度阈值进行编程,从而使主机能够自定义热负荷曲线。该充电器针对 5V USB 输入进行了优化,具有 20V 的绝对最大容差,可承受线路瞬变。该器件还集成了一个用于为无线电或处理器提供静态轨的线性稳压器,可以通过 I²C 独立地为其提供电源并对其进行控制。



6 Device Comparison Table

表 6-1. Device Comparison

PARAMETER	BQ21061	BQ21062
ICHARGE (default)	10mA	67.5mA
IPRECHARGE (default)	2.5mA	8.75mA
INLIM (default)	500mA	100mA
WATCHDOG TIMER (default)	Enabled	Disabled
VINDPM (default)	Disabled	Enabled
DPPM	Enabled	Disabled
LS/LDO (default)	Enabled	Disabled
LDO CONFIG (default)	LDO	Load Switch
BATUVLO (default)	3V	2.8V
MR HW RESET (default)	8s	14s
AUTOWAKE TIME (default)	1.2s	2.4s
TS THRESHOLD (default)	TWARM = 45°C; THOT = 60°C	TWARM = THOT = 45°C



7 Pin Configuration and Functions

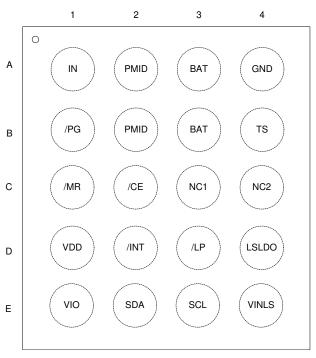


图 7-1. YFP Package 20-Pin DSBGA Top View

表 7-1. Pin Functions

ı	PIN	I/O	DESCRIPTION		
NAME	NO.	1/0	DESCRIPTION		
IN	A1	I	DC Input Power Supply. IN is connected to the external DC supply. Bypass IN to GND with at least 1-µF of capacitance using a ceramic capacitor.		
PMID	A2, B2	I/O	Regulated System Output. Connect 22-µF capacitor from PMID to GND as close to the PMID and GND pins as possible. If operating in VIN Pass-Through Mode (PMID_REG = 111) a lower capacitor value may be used (at least 3-µF of ceramic capacitance with DC bias de-rating).		
GND	A4	PWR	Ground connection. Connect to the ground plane of the circuit.		
VDD	D1	0	Digital supply LDO. Must connect a 2.2-µF from this pin to ground, do not leave floating.		
CE C2 Charge Enable. Drive CE low or leave disconnected to enable charging when VIN is valid CE is pulled low internally with 900-k Ω resistor.					
SCL	E3	I/O	I ² C Interface Clock. Connect SCL to the logic rail through a 10-k Ω resistor.		
SDA	E2	I	I^2 C Interface Data. Connect SDA to the logic rail through a 10-k $Ω$ resistor.		
LΡ	D3	I	Low Power Mode Enable. Drive this pin low to set the device in low power mode when powered by the battery. This pin must be driven high to allow I^2C communication when VIN is not present. \overline{LP} is pulled low internally with 900-k Ω resistor. This pin has no effect when VIN is present.		
INT	D2	0	INT is an open-drain output that signals fault interrupts. When a fault occurs, a 128-μs pulse is sent out as an interrupt for the host.		
MR	C1	I	Manual Reset Input. $\overline{\text{MR}}$ is a general purpose input used to reset the device or to wake it up from Ship Mode. $\overline{\text{MR}}$ has in internal 125-k Ω pull-up resistor to BAT. The battery voltage V_{BAT} must be above V_{BATUVLO} in order for $\overline{\text{MR}}$ low logic level to be detected.		
LS/LDO	D4	0	Load Switch or LDO output. Connect 2.2 µF of ceramic capacitance to this pin to assure stability. Be sure to account for capacitance bias voltage derating when selecting the capacitor. If LDO is not used, short to VINLS		
VINLS	E4	I	Input to the Load Switch / LDO output. Connect at least 1 μF of ceramic capacitance from this pin to ground.		



表 7-1. Pin Functions (continued)

P	IN	I/O	DESCRIPTION	
NAME	NO.	1/0	DESCRIPTION	
BAT	A3, B3	I/O	Battery Connection. Connect to the positive terminal of the battery. Bypass BAT to GND with at least 1 μ F of ceramic capacitance.	
TS	B4	Battery Pack NTC Monitor. Connect TS to a 10-k Ω NTC thermistor in parallel to a 10-k Ω resistor. If TS function is not to be used connect a 5-k Ω resistor from TS to ground.		
PG	B1	0	Open-drain Power Good status indication output. The \overline{PG} pin can also be configured as eneral purpose open drain output or level shifter version of \overline{MR} .	
VIO	E1	I	System IO supply. Connect to system IO supply to allow level shifting of input signals (SDA, SCL, LP and CE) to the device internal digital domain. Connect to VDD when external IO supply is not available.	
NC1	C3	I	No Connect. Connect to ground if possible for better thermal dissipation or leave floating. Do not connect to a any voltage source or signal to avoid higher quiescent current.	
NC2	C4	I	No Connect. Connect to ground if possible for better thermal dissipation. May be shorted to /LP for easier routing as long as Absolute Maximum Rating requirements are met	

8 Specifications

8.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

		MIN	MAX	UNIT
	IN	- 0.3	20	V
Voltage	TS,VDD, NC	- 0.3	1.95	V
	All other pins	- 0.3	5.5	V
	IN	0	800	mA
Current	BAT, PMID	- 0.5	1.5	Α
Current	INT, PG	0	10	mA
Junction temper	erature, T _J	- 40	125	°C
Storage tempe	rature, T _{stg}	- 55	150	°C

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Rating may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Condition. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

8.2 ESD Ratings

			VALUE	UNIT
V	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/ JEDEC JS-001, all pins ⁽¹⁾	±2000	V
V _(ESD)	Electrostatic discharge	Charged device model (CDM), per JEDEC specification JESD22-C101, all pins ⁽²⁾	±500	V

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

8.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM MAX	UNIT
V_{BAT}	Battery voltage range	2.4	4.6	V
V _{IN}	Input voltage range	3.15	5.25 ⁽¹⁾	V
V _{INLS}	LDO input voltage range	2.2	5.25 ⁽¹⁾	V
V _{IO}	IO supply voltage range	1.2	3.6	V
I _{LDO}	LDO output current	0	100	mA
I _{PMID}	PMID output current	0	1.5	Α
T _A	Operating free-air temperature range	- 40	85	°C

⁽¹⁾ Based on minimum V_{OVP} value. 5.5V under typical conditions

8.4 Thermal Information

		BQ21062	
	THERMAL METRIC(1)	YFP (DSBGA)	UNIT
		20-PIN	
R ₀ JA	Junction-to-ambient thermal resistance (2)	36.1	°C/W
R ₀ JA	Junction-to-ambient thermal resistance	74.4	°C/W
R _{θ JC(top)}	Junction-to-case (top) thermal resistance	0.5	°C/W
R _{θ JB}	Junction-to-board thermal resistance	17.6	°C/W
ΨЈТ	Junction-to-top characterization parameter	0.3	°C/W

Copyright © 2023 Texas Instruments Incorporated

Submit Document Feedback

7



8.4 Thermal Information (continued)

		BQ21062	
	THERMAL METRIC(1)	YFP (DSBGA)	UNIT
		20-PIN	
Ψ ЈВ	Junction-to-board characterization parameter	17.7	°C/W
R _{θ JC(bot)}	Junction-to-case (bottom) thermal resistance	N/A	°C/W

⁽¹⁾ For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

8.5 Electrical Characteristics

 V_{IN} = 5V, V_{BAT} = 3.6V, -40°C < T_{J} < 125°C unless otherwise noted. Typical data at T_{J} = 25°C.

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
INPUT CL	JRRENTS					
	In a second control of the second of the sec	PMID_MODE = 01, V _{IN} = 5V, V _{BAT} = 3.6V			500	μA
I _{IN}	Input supply current	V _{IN} = 5V, V _{BAT} = 3.6V Charge Disabled			1.6	mA
I _{BAT_SHIP}	Battery Discharge Current in Ship Mode	V _{IN} = 0V , V _{BAT} = 3.6V		10		nA
ı	Battery Quiescent Current in Low-power	V _{IN} = 0V , V _{BAT} = 3.6V, LDO Disabled		0.46	0.9	μΑ
BAT_LP	Mode	V _{IN} = 0V , V _{BAT} = 3.6V, LDO Enabled		1.7	1.9	μΑ
BAT_ACTI	Pottom, Ouisseent Current in Active Mede	V _{IN} = 0V , V _{BAT} = 3.6V, LDO Disabled		18	23	μΑ
VE _	Battery Quiescent Current in Active Mode	V _{IN} = 0V , V _{BAT} = 3.6V, LDO Enabled		21	25	μΑ
POWER F	PATH MANAGEMENT AND INPUT CURRE	NT LIMIT				
V _{PMID_RE}	Default System (PMID) Regulation Voltage			4.5		V
V _{PMID_RE}	System Regulation Voltage Acquirecy	V _{IN} = 5V, V _{PMID_REG} = 4.5V. I _{PMID} = 100mA, T _J = 25°C	-1		1	%
G_ACC	System Regulation Voltage Accuracy	V _{IN} = 5V, V _{PMID_REG} = 4.5V. I _{PMID} = 0- 500mA	- 3		3	%
R _{ON(IN-} PMID)	Input FET ON resistance	I _{ILIM} = 500mA (ILIM = 110), V _{IN} = 5V, I _{IN} = 150mA		280	520	mΩ
V _{BSUP1}	Enter supplements mode threshold	V _{BAT} > V _{BATUVLO} , Charge disabled		V _{PMID} < V _{BAT} - 40mV		mV
V _{BSUP2}	Exit supplements mode threshold	V _{BAT} > V _{BATUVLO} , Charge disabled		V _{PMID} < V _{BAT} - 20mV		mV
		Programmable Range	50		600	mA
		I _{ILIM} = 50mA		45	50	mA
I _{ILIM}	Input Current Limit	I _{ILIM} = 100mA		90	100	mA
		I _{ILIM} = 150mA		135	150	mA
		I _{ILIM} = 500mA		450	500	mA
V _{IN_DPM}	Input DPM voltage threshold where current in reduced	Programmable Range	4.2		4.9	V
	Accuracy		- 3		3	%
BATTERY	CHARGER	·				
R _{ON(BAT-}	Battery Discharge FET On Resistance	V _{BAT} = 4.35V, I _{BAT} = 100mA		100	175	mΩ
\	Charge Voltage	Programmable charge voltage range	3.6		4.6	V
V_{BATREG}	Voltage Regulation Accuracy		0.5		0.5	%

Submit Document Feedback

Copyright © 2023 Texas Instruments Incorporated

⁽²⁾ Measured in BQ21062EVM board.

8.5 Electrical Characteristics (continued)

 V_{IN} = 5V, V_{BAT} = 3.6V, -40°C < T_J < 125°C unless otherwise noted. Typical data at T_J = 25°C.

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
I _{CHARGE}	Fast Charge Programmable Current Range	V _{LOWV} < V _{BAT} < V _{BATREG}	1.25			mA
	Fast Charge Current Accuracy	I _{CHARGE} > 5mA	- 5		5	%
PRECHAR	Precharge current	Precharge current programmable range	1.25			mA
GE	Precharge Current Accuracy	-40°C < T _J < 85°C	- 10		10	%
I _{TERM}	Termination Charge Current	Termination Current Programmable Range	1		31	%
	Accuracy	I _{TERM} = 10% I _{CHARGE} , I _{CHARGE} = 100mA	- 5 ⁽¹⁾		5 ⁽¹⁾	%
V_{LOWV}	Programmable voltage threshold for pre- charge to fast charge transitions	VBAT rising. Programmable Range	2.8		3	V
V _{SHORT}	Battery voltage threshold for short detection	VBAT falling, VIN = 5V	2.41	2.54	2.67	V
I _{SHORT}	Charge Current in Battery Short Condition	V _{BAT} < V _{SHORT}	I	PRECHAR GE		mA
V_{RCH}	Recharge Threshold voltage	V _{BAT} falling, V _{BATREG} = 4.2V, V _{RCH} = 140mV setting		140		mV
▼ RCH	recentage Threshold voltage	$V_{\rm BAT}$ falling, $V_{\rm BATREG}$ = 4.2V, $V_{\rm RCH}$ = 200mV setting		200		mV
R _{PMID_PD}	PMID pull-down resistance	V _{PMID} = 3.6V		25		Ω
VDD						
V_{DD}	VDD LDO output voltage			1.8		V
LS/LDO						
	Input voltage range for Load switch Mode		0.8		5.5	V
V _{INLS}	Input voltage range for LDO Mode		2.2 or V _{LDO} + 500mV		5.5	V
	LDO programmable output voltage range		0.6		3.7	V
V_{LDO}		T _J = 25°C	- 2		2	%
	LDO output accuracy	V _{LDO} = 1.8V, V _{INLS} =3.6V. I _{LOAD} = 1mA	- 3		3	%
Δ V _{OUT} / Δ I _{OUT}	DC Load Regulation	0°C < T _J < 85°C, 1 mA < I _{OUT} < 150mA, V _{LDO} = 1.8V		1.2		%
Δ V _{OUT} / Δ V _{IN}	DC Line Regulation	0°C < T _J < 85°C, Over V _{INLS} range, I _{OUT} = 100mA, V _{LDO} = 1.8V		0.5		%
	Switch On resistance	V _{INLS} = 3.6V		250	450	mΩ
R _{DSCH_LS}	Discharge FET On-resistance for LS	V _{INLS} = 3.6V		40		Ω
I _{OCL_LDO}	Output Current Limit	V _{LS/LDO} = 0V	200	300		mA
I _{IN LDO}	LDO VINLS quiescent current in LDO mode	V _{BAT} = V _{INLS} =3.6V		0.9		μΑ
	OFF State Supply Current	$V_{BAT} = V_{INLS} = 3.6V$		0.25		μΑ
BATTERY	PACK NTC MONITOR					
V _{HOT}	High temperature threshold	V _{TS} falling, -10°C < T _J < 85°C	0.256(1)	0.265	0.268(1)	V
V _{WARM}	Warm temperature threshold	V _{TS} falling, -10°C < T _J < 85°C	0.256 ⁽¹⁾	0.265	0.268(1)	V
V _{COOL}	Cool temperature threshold	V _{TS} rising, -10°C < T _J < 85°C	0.510 ⁽¹⁾	0.514	0.523(1)	V
V _{COLD}	Cold temperature threshold	V _{TS} rising, -10°C < T _J < 85°C	0.581 ⁽¹⁾	0.585	0.594(1)	V
V _{OPEN}	TS Open threshold	V _{TS} rising, -10°C < T _J < 85°C		0.9		V
V _{HYS}	Threshold hysteresis			4.7		mV



8.5 Electrical Characteristics (continued)

 V_{IN} = 5V, V_{BAT} = 3.6V, -40°C < T_J < 125°C unless otherwise noted. Typical data at T_J = 25°C.

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
I _{TS_BIAS}	TS bias current	-10°C < T _J < 85°C	78.4	80	81.6	μA
PROTEC	TION					
V	IN active threshold voltage	V _{IN} rising		3.4		V
V_{UVLO}	IN active threshold voltage	V _{IN} falling		3.25		V
	Battery undervoltage Lockout Threshold Voltage	Programmable range, 150 mV Hysteresis	2.4		3	V
$V_{BATUVLO}$	Accuracy		- 3		3	%
	Battery undervoltage Lockout Threshold Voltage at Power Up	V _{BAT} rising, V _{IN} = 0V, T _J = 25°C		3.15		V
V _{SLP_ENT}	Sleep Entry Threshold (V _{IN} - V _{BAT})	2.0V < V _{BAT} < V _{BATREG} , V _{IN} falling		80		mV
V _{SLP_EXIT}	Sleep Exit Threshold (V _{IN} - V _{BAT})	2.0V < V _{BAT} < V _{BATREG}		130		mV
V	Input Supply Over Voltage Threshold	V _{IN} rising	5.35	5.5	5.8	V
V _{OVP}	input Supply Over voltage Threshold	V _{IN} falling (125mV hysteresis)		5.4		V
I _{BAT_OCP}	Battery Over Current Threshold Programmable range	I _{BAT_OCP} increasing	1200		1600	mA
_	Current Limit Accuracy		- 30		30	%
T _{SHUTDO} WN	Thermal shutdown trip point			125		°C
T _{HYS}	Thermal shutdown trip point hysteresis			15		°C
I ² C INTER	RFACE (SCL and SDA)				·	
	I ² C Frequency		100		400	kHz
V _{IL}	Input Low threshold level	V _{PULLUP} = V _{IO} = 1.8V			0.25 * V _{IO}	V
V _{IH}	Input High Threshold level	V _{PULLUP} = V _{IO} = 1.8V	0.75 * V _{IO}			V
V _{OL}	Output Low threshold level	V _{PULLUP} = V _{IO} = 1.8V, I _{LOAD} = 5mA			0.25 * V _{IO}	V
I _{LKG}	High-level leakage Current	V _{PULLUP} = V _{IO} = 1.8V			1	μA
/MR INPU	ıт					
R _{PU}	Internal pull up resistance		90	125	170	$\mathbf{k} \Omega$
V _{IL}	/MR Input Low threshold level	$V_{BAT} > V_{BUVLO}$			0.3	V
/INT, /PG	OUTPUTS					
V _{OL}	Output Low threshold level	V _{PULLUP} = V _{IO} = 1.8V, I _{LOAD} = 5mA			0.25 * V _{IO}	V
I _{LKG}	/INT Hi level leakage Current	High Impedance, V _{PULLUP} = V _{IO} = 1.8V			1	μA
/CE, /LP I	NPUTS					
R _{PDOWN}	/CE pull down resistance			900		kΩ
V _{IL}	Input Low threshold level	V _{IO} = 1.8V			0.45	V
V _{IH}	/CE Input High Threshold level	V _{IO} = 1.8V	1.35			V

(1) Based on Characterization Data

8.6 Timing Requirements

PARAMETER	TEST CONDITIONS	MIN	TYP MAX	UNIT
BATTERY CHARGE TIMERS				
t _{MAXCHG} Charge safety timer	Programmable range	180	720	min

Submit Document Feedback

Copyright © 2023 Texas Instruments Incorporated

10



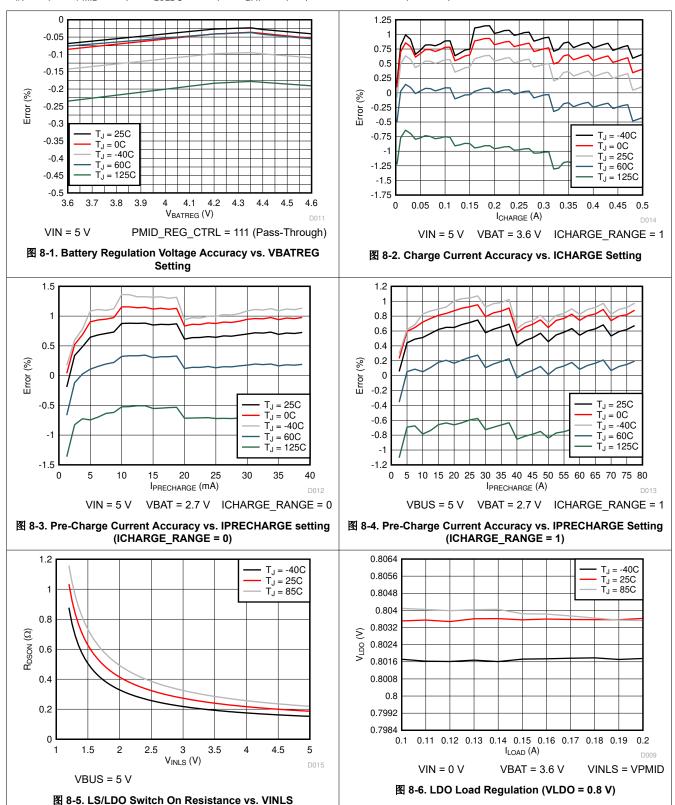
8.6 Timing Requirements (continued)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t _{PRECHG} Precharge safety timer				0.25 *	t _{MAXCHG}	
WATCHD	OG TIMERS					
t _{WATCHDO} G_SW	SW Watchdog timer		25	50		s
t _{HW_RESE} T_WD	HW reset watchdog timer	HWRESET_14S_WD = 1			14	s
LDO			·			
t _{ON_LDO}	Turn ON time	100mA load, to 90% V _{LDO}		500		μs
t _{OFF_LDO}	Turn OFF time	100mA load, to 10% V _{LDO}		30		μs
t _{PMID_LDO} _DELAY	Delay between PMID and LDO enable during power up	Startup		20		ms
PUSHBU	TTON TIMERS (/MR)		·			
t _{WAKE1}	WAKE1 Timer. Timer for Ship Mode wake.	MR_WAKE1_TIMER = 0	106	125	144	ms
t _{WAKE2}	WAKE2 Timer. Time from /MR falling edge to INT being asserted.	MR_WAKE2_TIMER = 1	1.7	2	2.3	S
t _{RESET_W} ARN	RESET_WARN Timer. Time prior to HW RESET or entering shipmode with MR press	MR_RESET_WARN = 01	0.85	1	1.15	s
t _{HW_RESE} T	HW RESET Timer. Time from /MR falling edge to HW Reset or PMID falling for shipmode entry	MR_HW_RESET = 01	6.8	8	9.2	s
t _{RESTART(} AUTOWAKE)	RESTART Timer. Time from /MR HW Reset to PMID power up	AUTOWAKE = 01	1.05	1.2	1.35	s
PROTEC [*]	TION					
t _{DGL_SLP}	Deglitch time for supply rising above $V_{SLP} + V_{SLP_HYS}$			120		μs
t _{DGL_OVP}	Deglitch time for V _{OVP} Threshold	VIN falling below V _{OVP}		32		ms
t _{DGL_OCP}	Battery OCP deglitch time			30		μs
t _{REC_SC}	Recovery time, BAT Short Circuit during Discharge Mode			250		ms
t _{RETRY_SC}	Retry window for PMID or BAT short circuit recovery			2		s
t _{DGL_SHT}	Deglitch time, Thermal shutdown	T _J rising above T _{SHUTDOWN}		10		μs
I2C INTE	RFACE					
t _{WATCHDO} G	I ² C interface reset timer for host	When enabled		50		s
t _{I2CRESET}	I ² C interface inactive reset timer			500		ms
INPUT PI	NS (/CE and /LP)		·			
t _{LP_EXIT_I}	Time for device to exit Low-power mode and allow I ² C communication	V _{IN} = 0V.			1	ms
		1				



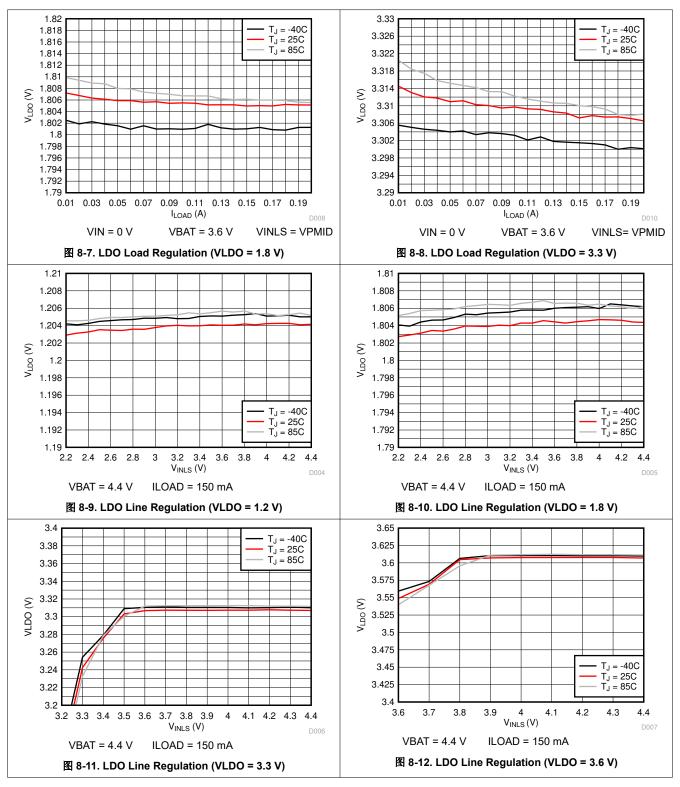
8.7 Typical Characteristics

 C_{IN} = 1 μ F, C_{PMID} = 10 μ F, C_{LSLDO} = 2.2 μ F, C_{BAT} = 1 μ F (unless otherwise specified)



8.7 Typical Characteristics (continued)

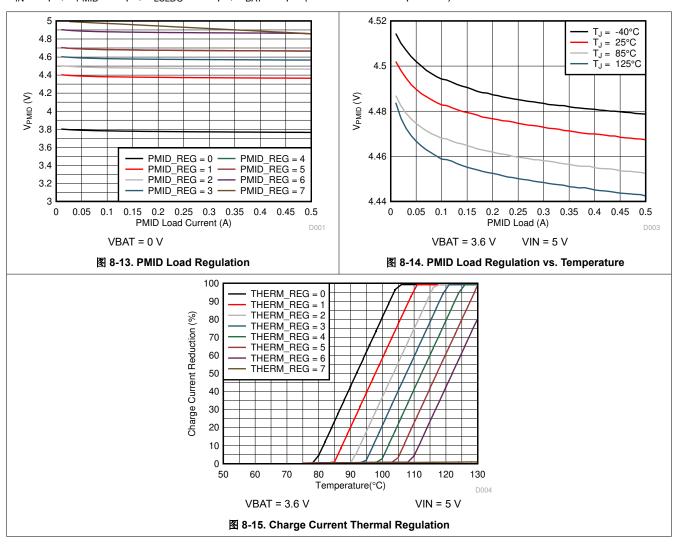
 C_{IN} = 1 μ F, C_{PMID} = 10 μ F, C_{LSLDO} = 2.2 μ F, C_{BAT} = 1 μ F (unless otherwise specified)





8.7 Typical Characteristics (continued)

 C_{IN} = 1 $\mu\text{F},\,C_{PMID}\text{=}\ 10~\mu\text{F},\,C_{LSLDO}\text{=}\ 2.2~\mu\text{F},\,C_{BAT}\text{=}\ 1~\mu\text{F}}$ (unless otherwise specified)



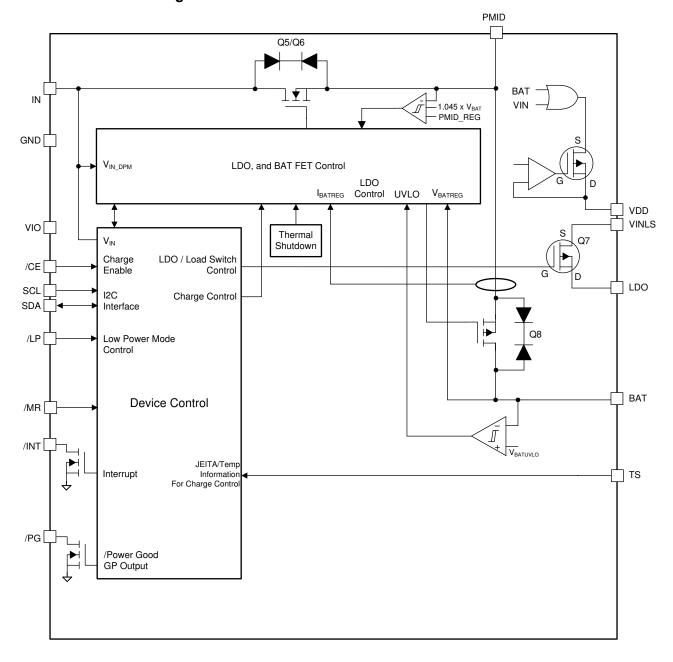


9 Detailed Description

9.1 Overview

The IC is a highly programmable battery management device that integrates a 500-mA linear charger for single cell Li-lon batteries, a general purpose LDO that may be configured as a load switch, and a push-button controller. Through it's I²C interface the host may change charging parameters such as battery regulation voltage and charge current, and obtain detailed device status and fault information. The push-button controller allows the user to reset the system without any intervention from the host and wake up the device from Ship Mode.

9.2 Functional Block Diagram



9.3 Feature Description

9.3.1 Linear Charger and Power Path

The BQ21062 IC integrates a linear charger that allows the battery to be charged with a programmable charge current of up to 500 mA. In addition to the charge current, other charging parameters can be programmed through I²C such as the battery regulation voltage, pre-charge current, termination current, and input current limit current.

The power path allows the system to be powered from PMID, even when the battery is dead or charging, by drawing power from IN pin. It also prioritizes the system load connected to PMID, reducing the charging current, if necessary, in order to support the load when input power is limited. If the input supply is removed and the battery voltage level is above V_{BATUVLO}, PMID will automatically and seamlessly switch to battery power.

A more detailed description of the charger functionality is presented in the following sections of this document.

9.3.1.1 Battery Charging Process

The following diagram summarizes the charging process of the BQ21062 charger.

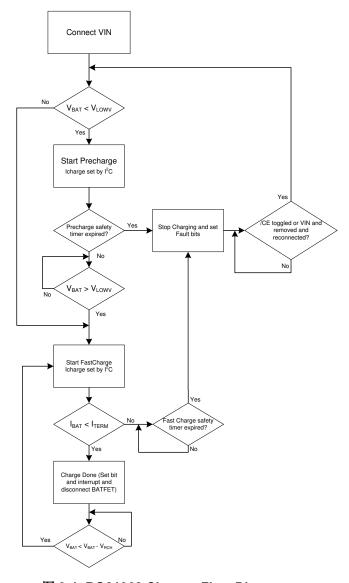


图 9-1. BQ21062 Charger Flow Diagram

When a valid input source is connected ($V_{IN} > V_{UVLO}$ and $V_{BAT} + V_{SLP} < V_{IN} < V_{OVP}$), the state of the \overline{CE} pin determines whether a charge cycle is initiated. When the \overline{CE} input is high and a valid input source is connected, the battery charge FET is turned off, preventing any kind of charging of the battery. A charge cycle is initiated when the CHARGE_DISABLE bit is written to 0 and \overline{CE} pin in low. $\frac{1}{8}$ 9-1 shows the \overline{CE} pin and bit priority to enable/disable charging.

表 9-1. Charge	Enable	Function	Through	CE Dir	and CE Bit

CE PIN	CHARGE _DISABLE BIT	CHARGING
0	0	Enabled
0	1	Disabled
1	0	Disabled
1	1	Disabled

图 9-2 shows a typical charge cycle.

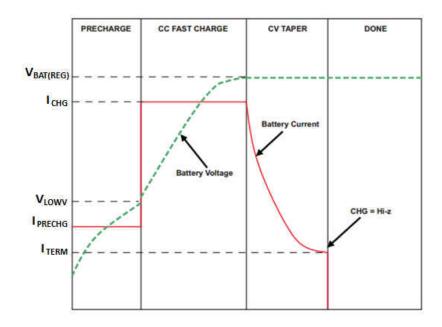


图 9-2. BQ21062 Typical Charge Cycle

During Pre-Charge, where the battery voltage is below the V_{LOWV} level, the battery will be charge with $I_{PRECHARGE}$ current which can be programmed through I^2C . During pre-charge, the safety timer is set to 25% of the safety timer value during fast charge. Once the battery voltage reaches V_{LOWV} , the charger will then operate in Fast Charge Mode, charging the battery at I_{CHARGE} which may also be programmed through I_2C . Once the battery voltage approaches the V_{BATREG} level, the charging current starts tapering off as shown in \mathbb{Z} 9-2. Once the charging current reaches the termination current (I_{TERM}) charging is stopped. Note that to ensure that the battery is charged to V_{BATREG} level, the regulated PMID voltage should be set to at least 200mV above V_{BATREG} . Termination is only enabled when the charger CV loop is active in fast charge operation. No termination will occur if the charge current reaches I_{TERM} while VINDPM is active as well as the thermal regulation loop. Termination is also disabled when operating in the TS WARM region. The charger only goes to termination when the current drops to I_{TERM} due to the battery reaching the target voltage and not due to the charge current limitation imposed by the previously mentioned control loops

Whenever a change in the charge current setting is triggered, whether it occurs due to I^2C programming by the host, Pre-Charge/Fast Charge transition or JEITA TS control, the device will temporarily disable charging (for ~ 1 ms) before updating the charge current value.

9.3.1.2 JEITA and Battery Temperature Dependent Charging

The charger can be configured through I²C setting to provide JEITA support, automatically reducing the charging current and voltage depending on the battery temperature as monitored by an NTC thermistor connected to the BQ21062 TS pin. See † 9.3.11 for details.

9.3.1.3 Input Voltage Based Dynamic Power Management (VINDPM)

The VINDPM loop prevents the input voltage from collapsing to a point where charging would be interrupted by reducing the current drawn by charger in order to keep V_{IN} from dropping below V_{IN DPM}. Once the IN voltage drops to V_{IN DPM}, the VINDPM loops will reduce the input current through the blocking FETs, to prevent the further drop of the supply voltage. The VINDPM function is enabled by default and may be disabled through I2C command. The V_{IN DPM} threshold is programmable through the I²C register from 4.2 V to 4.9 V in 100-mV steps.

DPPM is disabled by default in this device and cannot be re-enabled through I²C. When the device enters this mode, the charge current may be lower than the set value and the corresponding status bits and flags are set. If the 2X timer is set, the safety timer is extended while the loop is active. Additionally, termination is disabled.

9.3.1.4 Battery Supplement Mode

When the PMID voltage drops below the battery voltage by V_{BSUP1}, the battery supplements the system load. The battery stops supplementing the system load when the voltage on the PMID pin rises above the battery voltage by V_{RSUP2}. During supplement mode, the battery supplement current is not regulated, however, the Battery Over-Current Protection mechanism is active. Battery charge termination is disabled while in supplement mode.

9.3.2 Protection Mechanisms

9.3.2.1 Input Over-Voltage Protection

The input over-voltage protection protects the device and downstream components connected to PMID, and BAT against damage from over-voltage on the input supply. When $V_{IN} > V_{OVP}$ an OVP fault is determined to exist. During the OVP fault, the device turns the input FET off, sends a single 128-µs pulse on INT, and the VIN OVP FAULT FLAG and STAT bits are updated over I²C. Once the OVP fault is removed, the STAT bit is cleared and the device returns to normal operation. The FLAG bit is not cleared until it is read through I²C after the OVP condition no longer exists. The OVP threshold for the device is 5.5 V to allow operation from standard USB sources.

9.3.2.2 Safety Timer and I²C Watchdog Timer

At the beginning of the charge cycle, the device starts the safety timer. If charging has not terminated before the programmed safety time, t_{MAXCHG}, expires, charging is disabled. The pre-charge safety time, t_{PRECHG}, is 25% of t_{MAXCHG} . When a safety timer fault occurs, a single 128-µs pulse is sent on the $\overline{\text{INT}}$ pin and the SAFETY_TMR_FAULT_FLAG bit in the FLAG3 register is updated over I2C. The CE pin or input power must be toggled in order to reset the safety timer and exit the fault condition. Note that the flag bit will be reset when the bit is read by the host even if the fault has not been cleared. The safety timer duration is programmable using the SAFETY TIMER bits. When the safety timer is active, changing the safety timer duration resets the safety timer. The device also contains a 2X_TIMER bit that doubles the timer duration to prevent premature safety timer expiration when the charge current is reduced by VIN DPM, thermal regulation, or a NTC (JEITA) condition. When 2X TIMER function is enabled, the timer is allowed to run at half speed when any loop is active other than CC or CV.

In addition, the BQ21062 has a 50s watchdog timer which resets after every I²C transaction. This feature, which is disabled by default, resets all charger parameters registers to their default values when the timer expires.

9.3.2.3 Thermal Protection and Thermal Charge Current Foldback

In order to protect the device from damage due to overheating, the junction temperature of the die, T_J, is monitored. When T_J reaches T_{SHUTDOWN} the device stops operation and is turned off. The device resumes operation when T_J falls below T_{SHUTDOWN} by T_{HYS}.

Product Folder Links: BQ21062

Submit Document Feedback Copyright © 2023 Texas Instruments Incorporated During the charging process, the device will reduce the charging current at a rate of $(0.04 \text{ x I}_{CHARGE})$ /°C once T_J exceeds the thermal foldback threshold, T_{REG} to prevent further heating. If the charge current is reduced to 0, the battery supplies the current needed to supply the PMID output. The thermal regulation threshold may be set through I²C by setting the THERM_REG bits to the desired value.

The die junction temperature, T_J, can be estimated based on the expected board performance using 方程式 1:

$$T_J = T_A + \theta_{JA} \times P_{DISS} \tag{1}$$

Where P_{DISS} is the total power dissipation in the IC. The θ_{JA} is largely driven by the board layout. For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics Application Report*. Under typical conditions, the time spent in this state is very short.

9.3.2.4 Battery Short and Over Current Protection

In order to protect the device from over current and prevent excessive battery discharge current, the BQ21062 detects if the current on the battery FET exceeds I_{BAT_OCP} . If the short circuit limit is reached for the deglitch time (t_{DGL_OCP}) , the battery discharge FET is turned off and start operating in hiccup mode, re-enabling the BATFET t_{REC_SC} (250 ms) after being turned off by the over-current condition. If the over-current condition is triggered upon retry for 3 to 7 consecutive times, the BATFET will then remain off until the part is reset or until Vin is connected and valid. If the over-current condition and hiccup operation occurs while in supplement mode where VIN is already present, VIN must be toggled in order for BATFET to be enabled and start another detection cycle.

In the case where the battery is suddenly shorted while charging and VBAT drops below V_{SHORT} , a fast comparator quickly reduces the charge current to $I_{PRECHARGE}$ preventing fast charge current to be momentarily injected to the battery while shorted.

9.3.2.5 PMID Short Circuit

A short on the PMID pin is detected when the PMID voltage drops below 1.6 V (PMID short threshold). PMID short threshold has a 200-mV hysteresis. When this occurs, the input FET temporarily disconnects IN for up to 200 µs to prevent stress on the device if a sudden short condition happens, before allowing a softstart on the PMID output.

9.3.3 VDD LDO

The device integrates a low current always-on LDO that serves as the digital I/O supply to the device. This LDO is supplied by VIN or by BAT. The VDD LDO will remain on through all power states with the exception of Ship Mode.

9.3.4 Load Switch/LDO Output and Control

The device integrates a low Iq load switch which can also be used as a regulated output. The LDO/LS has a dedicated input pin VINLS and can support up to 150 mA of load current.

The LS/LDO may be enabled/disabled through I²C. The output voltage is programmable using the LS_LDO bits in the registers. To limit voltage drop or voltage transients, a small ceramic capacitor must be placed close to VINLS pin.

表 9-2. LDO Mode Control

• • • • • • • • • • • • • • • • • • •					
I2C EN_LS_LDO	LDO_SWITCH_CONFIG	LS/LDO OUTPUT			
0	0	Pulldown			
0	1	Pulldown			
1	0	LDO			
1	1	Load Switch			

Copyright © 2023 Texas Instruments Incorporated

Submit Document Feedback

19

The current capability of the LDO will depend on the VINLS input voltage and the programmed output voltage. When the LS/LDO output is disabled through the register, an internal pull-down will discharge the output. The LDO has output current limit protection, limiting the output current in the event of a short in the output. When the LDO output current limit trips and is active for at least 1 ms, the device will set a flag and send an interrupt to the host. The host must take action to enable the LDO if desired. The LS/LDO may be set to operate as a LDO by setting the LDO_SWITCH_CONFIG bit to 0. Note that in order to change the configuration, the LS/LDO must be disabled first, then the LDO_SWITCH_CONFIG bit is set for it to take effect. This is not the case when updating the LDO output voltage which can be done on the fly without the need of disabling the LDO first.

9.3.5 PMID Power Control

The BQ21062 offers the option to control PMID through the I 2 C PMID_MODE bits. These bits can force PMID to be supplied by BAT instead of IN, even if $V_{IN} > V_{BAT} + V_{SLP}$. They can also disconnect PMID, pulling it down or leaving it floating. See $\frac{1}{8}$ 9-30 for details.

9.3.6 System Voltage (PMID) Regulation

The BQ21062 has a regulated system voltage output (PMID) that is programmable through I^2C . PMID regulation is only active when the adapter is connected and $V_{IN} > V_{UVLO}$, $V_{IN} > V_{BAT} _ V_{SLP}$ and $V_{IN} < V_{OVP}$. In Battery Tracking operation (PMID_REG_CTRL = 000), the PMID voltage will be regulated to about 4.7% over battery level ($V_{PMID} = V_{BAT} \times 1.047$) or 3.8 V, whichever is higher. Note that the PMID regulation target should be set to be at least 200mV higher than V_{BATREG} .

9.3.7 MR Wake and Reset Input

The $\overline{\text{MR}}$ input has three main functions in the BQ21062. First, it serves as a means to wake the device from Ship Mode. Second, it serves as a short button press detector, sending an interrupt to the host when the button driving the $\overline{\text{MR}}$ pin has been pressed for a given period of time. This allows the implementation of different functions in the end application such as menu selection and control. And finally it serves as a means to get the BQ21062 to reset the system by performing a power cycle (shut down PMID and automatically powering it back on) or go to Ship Mode after detecting a long button press. In order for the $\overline{\text{MR}}$ to be functional, the battery voltage V_{BAT} must be above the V_{BATUVLO} level. The timing for the short and long button press duration is programmable through I²C for added flexibility. Note that if a specific timer duration is changed through I²C while that timer is active and has not expired, the new programmed value will be ignored until the timer expires and/or is reset by $\overline{\text{MR}}$. The $\overline{\text{MR}}$ input has an internal pull-up to BAT.

9.3.7.1 MR Wake or Short Button Press Functions

There are two programmable wake or short button press timers, WAKE1 and WAKE2. When the $\overline{\text{MR}}$ pin is held low for t_{WAKE1} the device sends an interrupt (128 μs active low pulse in the $\overline{\text{INT}}$ pin) and sets the MRWAKE1_TIMEOUT flag when it expires. If the $\overline{\text{MR}}$ pin continues to be driven low after WAKE1 and the WAKE2 timer expires, the BQ21062 sends a second interrupt and sets the MRWAKE2_TIMOUT flag. WAKE1 is used as the timer to wake the device from ship mode. WAKE2's only function is to send the interrupt and has no effect on other BQ21062 functions. These flags are not cleared until they have been read by the host. Note that interrupts are only sent when the flags are set and the flags must be cleared in order for another interrupt to be sent upon $\overline{\text{MR}}$ press. The timer durations can be set through the MR_WAKEx_TIMER bits in the MRCTRL Register section.

One of the main \overline{MR} functions is to wake the device from Ship Mode when the \overline{MR} is asserted. The device will exit the Ship Mode when the \overline{MR} pin is held low for at least t_{WAKE1} . Immediately after the \overline{MR} is asserted, VDD will be enabled and the digital will start the WAKE counter. If the \overline{MR} signal remains low until after the WAKE1 timer expires, the device will power up PMID and LDO (If enabled) completing the exit from the ship mode. If the \overline{MR} signal goes high before the WAKE1 timer expires, the device will go back to the Ship Mode operation, never powering up PMID or the LDO. Note that if the \overline{MR} pin remains low after exiting Ship Mode the wake interrupts will not be sent and the long button press functions like HW reset will not occur until the \overline{MR} pin is toggled. In the case where a valid V_{IN} ($V_{IN} > V_{UVLO}$) is connected prior to WAKE2 timer expiring, the device will exit the ship mode immediately regardless of the \overline{MR} or wake timer state. $\underline{\mathbb{Z}}$ 9-3 and $\underline{\mathbb{Z}}$ 9-4 show these different scenarios.

Product Folder Links: BQ21062

Copyright © 2023 Texas Instruments Incorporated

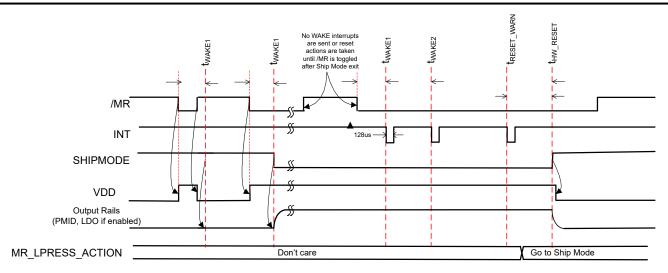


图 9-3. MR Wake from Ship Mode (MR_LPRESS_ACTION = Ship Mode, VIN not valid)

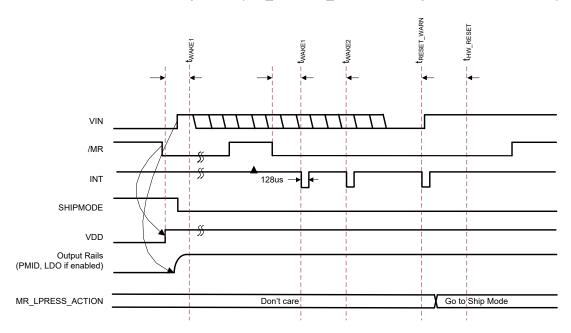


图 9-4. MR Wake from Ship Mode - VIN Dependencies

9.3.7.2 MR Reset or Long Button Press Functions

The BQ21062 device may be configured to perform a system hardware reset (Power Cycle/Autowake), go into Ship Mode, or simply do nothing after a long button press (for example, when the $\overline{\text{MR}}$ pin is driven low until the MR_HW_RESET timer expires). The action taken by the device when the timer expires is configured through the MR_LPRESS_ACTION bits in the ICCTRL1 Register section. Once the MR_HW_RESET timer expires the device immediately performs the operation set by the MR_LPRESS_ACTION bits. The BQ21062 sends an interrupt to the host when the device detects that $\overline{\text{MR}}$ has been pressed for a period that is within $t_{\text{RESET_WARN}}$ from reaching $t_{\text{HW_RESET}}$. This may warn the host that the button has been pressed for a period close to $t_{\text{HW_RESET}}$ which would trigger a HW Reset or used as another button press timer interrupt like the WAKE1 and WAKE2 timers. This interrupt is sent before the MR_HW_RESET timer expires and sets the MRRESET_WARN flag. The $t_{\text{RESET_WARN}}$ may be set through I²C by the MR_RESET_WARN bits in the MRCTRL register. The host may change the reset behavior at any time after $\overline{\text{MR}}$ going low and prior to the MR_HW_RESET timer expiring. It may not change it however from another behavior to a HW reset (Power Cycle/Autowake) since a HW reset can be gated by other condition requirements, such as a valid VIN presence (controlled by MR_RESET_VIN bit),



throughout the whole duration of the button press. This flexibility allows the host to abort any reset or power shutdown to the system by overriding a long button press command.

A HW reset may also be started by setting the HW_RESET bit. Note that during a HW reset , VDD remains on.

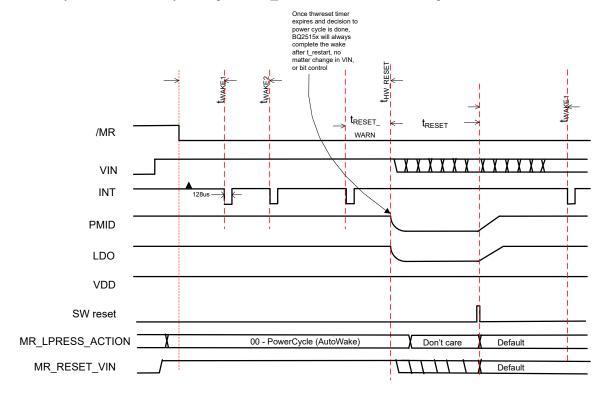


图 9-5. MR Wake and Reset Timing with VIN Present or BAT Active Mode When MR_LPRESS_ACTION = 00

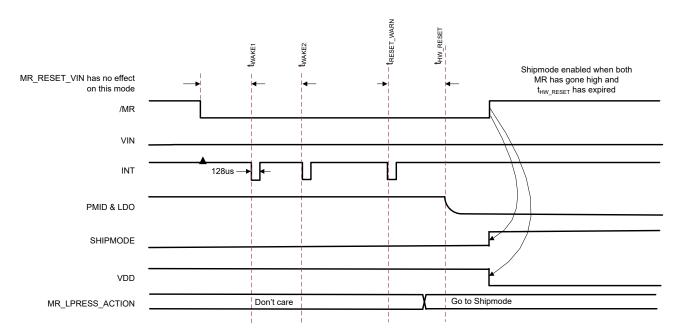


图 9-6. MR Wake and Reset Timing Active Mode When MR_LPRESS_ACTION = 1x (Ship Mode) and Only BAT is Present

9.3.8 14-Second Watchdog for HW Reset

The BQ21062 integrates a 14-second watchdog timer that makes the BQ21062 perform a HW reset/power cycle if no I^2C transaction is detected within 14 seconds of a valid adapter being connected. If the adapter is connected and the host responds with an I^2C transaction before the 14-second watchdog window expires, the part continues in normal operation. The 14-second watchdog is disabled by default and may be enabled through I^2C by setting the HWRESET_14S_WD bit. 89-7 shows the basic functionality of this feature.

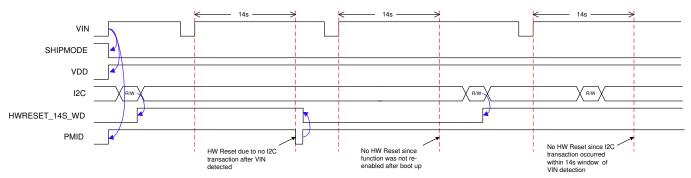


图 9-7. 14-Second Watchdog for HW Reset Behavior

9.3.9 Faults Conditions and Interrupts (INT)

The device contains an open-drain output that signals an interrupt and is valid only after the device has completed start-up into a valid state. If the part starts into a fault, interrupts will not be sent. The $\overline{\text{INT}}$ pin is normally in high impedance and is pulled low for 128 µs when an interrupt condition occurs. When a fault or status change occurs or any other condition that generates an interrupt such as CHARGE_DONE, a 128-µs pulse (interrupt) is sent on $\overline{\text{INT}}$ to notify the host. All interrupts may be masked through I^2C . If the interrupt condition occurs while the interrupt is masked an interrupt pulse will not be sent. If the interrupt is unmasked while the fault condition is still present, an interrupt pulse will not be sent until the $\overline{\text{INT}}$ trigger condition occurs while unmasked.

9.3.9.1 Flags and Fault Condition Response

表 9-3 below details the BQ21062 behavior when a fault condition occurs.

表 9-3. Interrupt Triggers and Fault Condition Response

FAULT / FLAG	DESCRIPTION	INTERRUPT TRIGGER BASED ON STATUS BIT CHANGE	CHARGER BEHAVIOR	CHARGER SAFETY TIMER	PMID BEHAVIOR
CHRG_CV_FLAG	Set when charger enters Constant Voltage operation	Rising Edge	Enabled	No effect	IN powered if V _{IN} is valid
CHARGE_DONE_FLA G	Set when charger reaches termination	Rising Edge	Paused- Charging resumes with VIN or CE toggle or when V _{RCH} is reached	Reset	IN powered if V _{IN} is valid
IINLIM_ACTIVE_FLAG	Set when Input Current Limit loop is active	Rising Edge	Enabled. Reduced charge current.	Doubled if option is enabled	IN powered VIN powered unless supplement mode condition is met.
VINDPM_ACTIVE_FL AG	Set when VINDPM loop is active	Rising Edge	Enabled. Reduced charge current.	Doubled if option is enabled	VIN powered unless supplement mode condition is met.



表 9-3. Interrupt Triggers and Fault Condition Response (continued)

	-pc o oi intorrape ii	iggere ama i a	uit Condition Resp	onee (continues)	
FAULT / FLAG	DESCRIPTION	INTERRUPT TRIGGER BASED ON STATUS BIT CHANGE	CHARGER BEHAVIOR	CHARGER SAFETY TIMER	PMID BEHAVIOR
THERMREG_ACTIVE	Set when Thermal Charge Current Foldback (Thermal Regulation) loop is active	Rising Edge	Enabled. Reduced charge current.	Doubled if option is enabled	VIN powered unless supplement mode condition is met.
VIN_PGOOD_FLAG	Set when VIN changes PGOOD status	Rising and Falling Edge	If VIN_PGOOD_STAT is low, charging is disabled.	Reset	VIN powered (if VIN_PGOOD_STAT =1) unless PMID_MODE is not 00.
VIN_OVP_FAULT_FL AG	Set when V _{IN} > V _{OVP}	Rising Edge	Charging is paused until condition disappears	Reset	BAT powered
BAT_OCP_FAULT_FL AG	Set when I _{BAT} > I _{BATOCP}	Rising Edge	Disabled (BAT only condition)	N/A	Disconnect BAT
BAT_UVLO_FAULT_F LAG	Set when V _{BAT} < V _{BATUVLO}	Rising Edge	Enabled	No effect	IN powered of V _{IN} is valid
TS_COLD_FLAG	Set when V _{TS} > V _{TS_COLD}	Rising Edge	Charging paused until condition is cleared	Paused	IN powered of V _{IN} is valid
TS_COOL_FLAG	Set when V _{TS_COLD} > V _{TS} > V _{TS_COOL}	Rising Edge	Enabled. Reduced charge current.	Doubled if option is enabled	IN powered of V _{IN} is valid
TS_WARM_FLAG	Set when V _{TS_HOT} < V _{TS} < V _{TS_WARM}	Rising Edge	Enabled. Reduce battery regulation voltage.	No effect	IN powered of V _{IN} is valid
TS_HOT_FLAG	Set when V _{TS} < V _{HOT}	Rising Edge	Charging paused until condition is cleared	Paused	IN powered of V _{IN} is valid
TS_OPEN_FLAG	Set when V _{TS} > V _{TS_OPEN}	Rising Edge	Charging is paused until condition disappears	Paused	N/A
WD_FAULT_FLAG	Set when I ² C watchdog timer expires	Rising Edge	Enabled	N/A	N/A
SAFETY_TMR_FAULT _FLAG	Set when safety Timer expires. Cleared after VIN or CE toggle	Rising Edge	Disabled until VIN or CE toggle	Reset after flag is cleared	IN powered of V _{IN} is valid
LS_LDO_OCP_FAULT _FLAG	Set when LDO output current exceeds OCP condition	Rising Edge	N/A	N/A	N/A
MRWAKE1_TIMEOUT _FLAG	Set when MR is low for at least t _{WAKE1}	Rising Edge	N/A	N/A	N/A
MRWAKE2_TIMEOUT _FLAG	Set when MR is low for at least t _{WAKE2}	Rising Edge	N/A	N/A	N/A
MRRESET_WARN_FL AG	Set when MR is low for at least t _{RESETWARN}	Rising Edge	N/A	N/A	N/A
TSHUT	No flag. Die temperature exceeds thermal shutdown threshold is reached	N/A	Disabled	Disabled	Disabled

9.3.10 Power Good (PG) Pin

The \overline{PG} pin is an open-drain output that by default indicates when a valid IN supply is present. It may also be configured to be a general purpose output (GPO) controlled through I²C or to be a level shifted version of the

ZHCSLK7A - JULY 2020 - REVISED APRIL 2023

 $\overline{\rm MR}$ input signal. Connect $\overline{\rm PG}$ to the desired logic voltage rail using a 1-k Ω to 100-k Ω resistor, or use with an LED for visual indication. See 表 9-30 for details.

9.3.11 External NTC Monitoring (TS)

The I²C interface allows the user to easily implement the JEITA standard for systems where the battery pack thermistor is monitored by the host. Additionally, the device provides a flexible voltage based TS input for monitoring the battery pack NTC thermistor. The voltage at TS is monitored to determine that the battery is at a safe temperature during charging. The TS pin is not biased continuously, instead it is biased only when the voltage at the pin is being sampled (for about 25ms in 225ms intervals when VIN is present. Note that the TS biasing cannot be disabled when VIN is present.

The part can be configured to meet JEITA requirements or a simpler HOT/COLD function only. Additionally, the TS charger control function can be disabled. To satisfy the JEITA requirements, four temperature thresholds are monitored: the cold battery threshold, the cool battery threshold, the warm battery threshold, and the hot battery threshold. These temperatures correspond to the V_{COLD} , V_{COOL} , V_{WARM} , and V_{HOT} thresholds in the Electrical Characteristics table. Charging and safety timers are suspended when $V_{TS} < V_{HOT}$ or $V_{TS} > V_{COLD}$. When V_{COOL} < V_{TS} < V_{COLD}, the charging current is reduced to the value programmed in the TS_FASTCHGCTRL register. Note that the current steps for fast charge in the COOL region, just as those in normal fast charge, are multiples of the fast charge LSB value (1.25 mA by default). So in the case where the calculated scaled down current for the COOL region falls in between charge current steps, the device will round down the charge current to the nearest step. For example, if the fast charge current is set for 15 mA (ICHG = 1100) and TS_FASTCHARGE =111 (0.125*ICHG), the charge current in the COOL region will be 1.25 mA instead of the calculated 1.85 mA.

When V_{HOT} < V_{TS} < V_{WARM}, the battery regulation voltage is reduced to the value programmed in the TS FASTCHGCTRL register.

Regardless of whether the part is configured for JEITA, HOT/COLD, or disabled, when a TS fault occurs, a 128us pulse is sent on the INT output, and the FAULT bits of the register are updated over I²C. The FAULT bits are not cleared until they are read over I2C. This allows the host processor to take action if a different behavior than the pre-set function is needed. Alternately, the TS pin voltage can be read by the host if VIN is present or when BAT is present, so the appropriate action can be taken by the host.

When in Battery only mode, a reading of the TS pin can be triggered to check for any TS faults. This is done by setting the TS_FAULT_MEAS_register (0x58) to 0x04 which sets the TS_FAULT_MEAS_ENABLE bit. The interval of the /INT interrupt can be configured in TS READ Register to either be a manual read or every second in the INTERVAL bit. When configured to manual read, the fault read will have to be iniated by setting the GET_FAULT_ENABLE bit which will automatically enable the I_{TS_BIAS} current on TS.

9.3.11.1 TS Thresholds

The BQ21062 monitors the TS voltage and sends an interrupt to the host whenever it crosses the V_{HOT}, V_{WARM}, V_{COOL} and V_{COLD} thresholds which correspond to different temperature thresholds based on the NTC resistance and biasing. These thresholds may be adjusted through I²C by the host. The device will also disable charging if TS pin exceeds the V_{TS OPEN} threshold.

The TS biasing circuit is shown in \boxtimes 9-8. Note that the respective V_{TS} for T_{COLD} (0°C), T_{COOL} (10°C), T_{WARM} (45°C) and T_{HOT} (60°C) changes for every NTC, therefore the threshold values may need to be adjusted through I²C based on the supported NTC type.



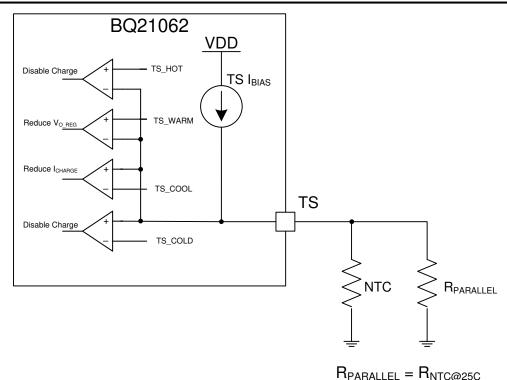


图 9-8. TS Bias Functional Diagram

The BQ21062 supports by default the following thresholds for a 10-K Ω NTC.

TEMPERATURE **THRESHOLD** VTS (V) (°C) Open >0.9 Cold 0 0.585 0.514 Cool 10 Warm 45⁽¹⁾ 0.265 45⁽¹⁾ 0.265 Hot

表 9-4. TS Thresholds for 10-K Ω Thermistor with 3380 B-Constant

9.3.12 I²C Interface

The BQ21062 device uses a fully compliant I²C interface to program and read control parameters, status bits, and so on. I²C is a 2-wire serial interface developed by Philips Semiconductor (see I²C-Bus Specification, Version 2.1, January 2000). The bus consists of a data line (SDA) and a clock line (SCL) with pull-up structures. When the bus is idle, both SDA and SCL lines are pulled high. All the I²C compatible devices connect to the I²C bus through open drain I/O pins, SDA and SCL. A master device, usually a micro-controller or a digital signal processor, controls the bus. The master is responsible for generating the SCL signal and device addresses. The master also generates specific conditions that indicate the START and STOP of data transfer. A slave device receives and/or transmits data on the bus under control of the master device.

The BQ21062 works as a slave and supports the following data transfer modes, as defined in the I²C Bus Specification: standard mode (100 kbps) and fast mode (400 kbps). The interface adds flexibility to the battery charge solution, enabling most functions to be programmed to new values depending on the instantaneous application requirements.

Register contents remain intact as long as VBAT or VIN voltages remains above their respective UVLO levels.

Copyright © 2023 Texas Instruments Incorporated

⁽¹⁾ When V_{HOT} is set to the same or higher voltage level as V_{WARM}, the WARM region is overwitten by HOT region functionality (charge is disabled).

The data transfer protocol for standard and fast modes is exactly the same; therefore, they are referred to as the F/S-mode in this document. The BQ21062 device 7-bit address is 0×6B (shifted 8-bit address is 0xD6).

9.3.12.1 F/S Mode Protocol

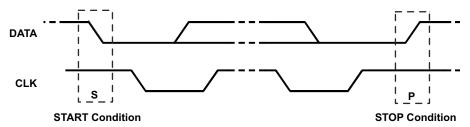


图 9-9. START and STOP Condition

The master then generates the SCL pulses, and transmits the 8-bit address and the read/write direction bit R/W on the SDA line. During all transmissions, the master ensures that data is valid. A valid data condition requires the SDA line to be stable during the entire high period of the clock pulse (see \$\mathbb{G}\$ 9-10). All devices recognize the address sent by the master and compare it to their internal fixed addresses. Only the slave device with a matching address generates an acknowledge (see \$\mathbb{G}\$ 9-11) by pulling the SDA line low during the entire high period of the ninth SCL cycle. Upon detecting this acknowledge, the master knows that communication link with a slave has been established.

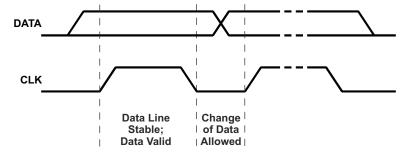


图 9-10. Bit Transfer on the Serial Interface

The master generates further SCL cycles to either transmit data to the slave (R/W bit 1) or receive data from the slave (R/W bit 0). In either case, the receiver needs to acknowledge the data sent by the transmitter. So an acknowledge signal can either be generated by the master or by the slave, depending on which one is the receiver. The 9-bit valid data sequences consisting of 8-bit data and 1-bit acknowledge can continue as long as necessary. To signal the end of the data transfer, the master generates a stop condition by pulling the SDA line from low to high while the SCL line is high (see § 9-9). This releases the bus and stops the communication link with the addressed slave. All I²C compatible devices must recognize the stop condition. Upon the receipt of a stop condition, all devices know that the bus is released, and wait for a start condition followed by a matching address. If a transaction is terminated prematurely, the master needs to send a STOP condition to prevent the slave I²C logic from remaining in an incorrect state. Attempting to read data from register addresses not listed in this section will result in FFh being read out.



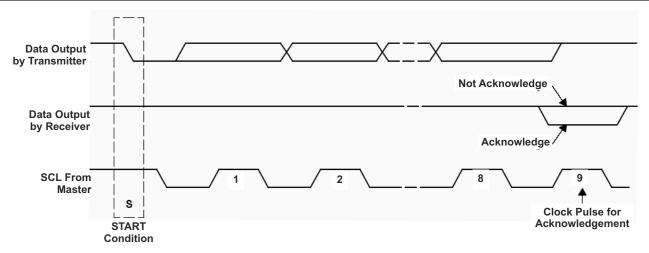


图 9-11. Acknowledge on the I²C Bus

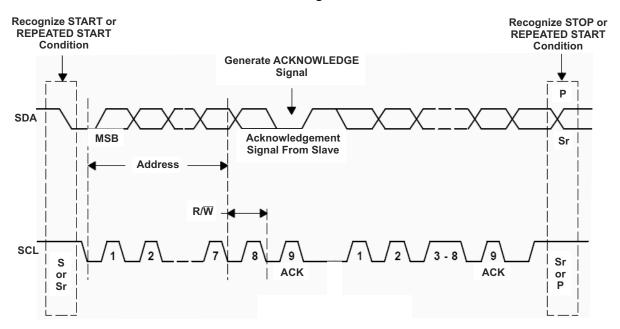


图 9-12. Bus Protocol

9.4 Device Functional Modes

The BQ21062 has four main modes of operation: Active Battery Mode, Low Power Mode and Ship Mode which are battery only modes and Charge/Adapter Mode when a supply is connected to IN. 表 9-5 below summarizes the functions that are active for each operation mode. Each mode is discussed in further detail in the following sections in addition to the device's power-up/down sequences.

表 9-5. Function Availability Based on Primary Mode of Operation

	Act of tunional training Europe and tuning mode of operation					
FUNCTION	CHARGE/ ADAPTER MODE	SHIP MODE	LOW POWER MODE	ACTIVE BATTERY MODE		
VOVP	Yes	No	Yes	Yes		
VUVLO	Yes	Yes	Yes	Yes		
BATOCP	Yes	No	No	Yes		
BATUVLO	Yes	No	Yes	Yes		
VINDPM	If enabled	No	No	No		
VDD	Yes	No	Yes	Yes		
LS/LDO	Yes	No	If enabled	If enabled		
BATFET	Yes	No	Yes	Yes		
TS Measurement	Yes	No	No	If enabled		
Battery Changing	If enabled	No	No	No		
ILIM	Yes (Register Value)	No	No	No		
MR input	Yes	Yes	Yes	Yes		
LP input	No	No	Yes	Yes		
INT output	Yes	No	No	Yes		
I ² C	Yes	No	No	Yes		
CE input	Yes	No	No	No		

9.4.1 Ship Mode

Ship Mode is the lowest quiescent current state for the device. Ship Mode latches off the device and BAT FET until $V_{IN} > V_{UVLO}$ or the \overline{MR} button is depressed for t_{WAKE1} and released. Ship mode can be entered regardless of the state of \overline{CE} . The device will also enter Ship Mode upon battery insertion when no valid VIN is present. If the EN_SHIPMODE is written to a 1 while a valid input supply is connected, the device will wait until the IN supply is removed to enter ship mode. If the \overline{MR} pin is held low when the EN_SHIPMODE bit is set, the device will wait until the \overline{MR} pin goes high before entering Ship Mode. $\boxed{8}$ 9-13 shows this behavior. The battery voltage must be above the maximum programmable $V_{BATUVLO}$ threshold in order to exit Ship Mode with \overline{MR} press. The EN_SHIPMODE bit can be cleared using the I²C interface while the VIN input is valid. The EN_SHIPMODE bit is not cleared upon the I²C watchdog expiring, this means that if watchdog timer fault occurs while the EN_SHIPMODE bit is set and the device is waiting to go into Ship Mode because V_{IN} is present or \overline{MR} is low, the device will still proceed to go into Ship Mode once those conditions are cleared.



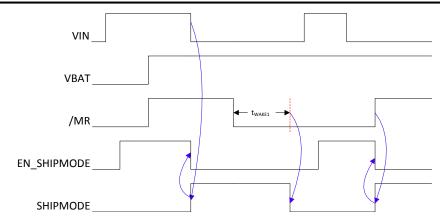


图 9-13. Ship Mode Entry Based On EN_SHIPMODE Bit

9.4.2 Low Power

Low Power mode is a low quiescent current state while operating from the battery. The device will operate in low power mode when the \overline{LP} pin is set low, $V_{IN} < V_{UVLO}$, \overline{MR} pin is high and all I²C transactions and interrupts that started while in the Active Battery or Charging Modes have been completed and sent. During LP mode the VDD output is powered by BAT, the \overline{MR} inputs are active and the I²C is disabled. All other circuits, such as oscillators, are in a low power or off state. The LS/LDO outputs will remain in the state set by the EN_LS_LDO bit prior to entering Low Power Mode. The device exits LP Mode when the \overline{LP} pin is set high or $V_{IN} > V_{UVLO}$.

In the case that a faulty adapter with $V_{IN} > V_{OVP}$ is connected to the device while \overline{LP} pin is low, the device will be powered from the battery, but will operate in Active battery mode instead of Low Power mode regardless of the \overline{LP} pin state.

When \overline{MR} is held low while \overline{LP} is low, the device will enter Active Battery Mode, this allows for the internal clocks of the device to be running and allow the \overline{MR} long button press HW reset. I²C operation is also possible during this condition. Note that as soon as the \overline{MR} input is released and goes high, the device will go back to LP Mode tuning off all clocks. Note that if a HW reset has occurred while \overline{LP} is low, \overline{MR} must remain low until the power cycle has completed (PMID and LDO enable) to allow completion of the power up sequence.

9.4.3 Active Battery

When the device is out of Ship Mode and battery is above $V_{BATUVLO}$ with no valid input source, the battery discharge FET is turned on connecting PMID to the battery. The current flowing from BAT to PMID is not regulated, but it is monitored by the battery over-current protection (OCP) circuitry. If the battery discharge current exceed the OCP threshold, the battery discharge FET will be turned off as detailed in \ddagger 9.3.2.4.

If only battery is connected and the battery voltage goes below $V_{BATUVLO}$, the battery discharge FET is turned off. To provide designers the most flexibility in optimizing their system, an adjustable BATUVLO is provided. Deeper discharge of the battery enables longer times between charging, but may shorten the battery life. The BATUVLO is adjustable with a fixed 150-mV hysteresis.

9.4.4 Charger/Adapter Mode

This mode is active when $V_{IN} > V_{UVLO}$. If the supply at IN is valid and above the V_{IN_DPM} level, PMID will be powered by the supply connected to IN. The device will charge the battery, if charging is enabled, until termination has occurred.

9.4.5 Power-Up/Down Sequencing

The power-up and power-down sequences for the BQ21062 are shown below. Upon V_{IN} insertion, VIN> V_{UVLO} , the device wakes up, powering the VDD rail. If $V_{IN} > V_{BAT} + V_{SLP}$ and $V_{IN} < V_{OVP}$, PMID will be powered by VIN and if $V_{IN} > V_{IN}$ ppm charging will start if enabled.

In the case where $V_{IN} < V_{UVLO}$ and the battery is inserted ($V_{BAT} > V_{BATUVLO}$), the device will immediately enter Ship Mode unless \overline{MR} is held low. Upon battery insertion the VDD rail will come up to allow the device to check

Copyright © 2023 Texas Instruments Incorporated

the $\overline{\text{MR}}$ state and if $\overline{\text{MR}}$ is high VDD will immediately be disabled and the device will enter Ship Mode. If $\overline{\text{MR}}$ is low, the device will start the WAKE timer and power up PMID and other rails if $\overline{\text{MR}}$ is held low for longer than t_{WAKE1} .

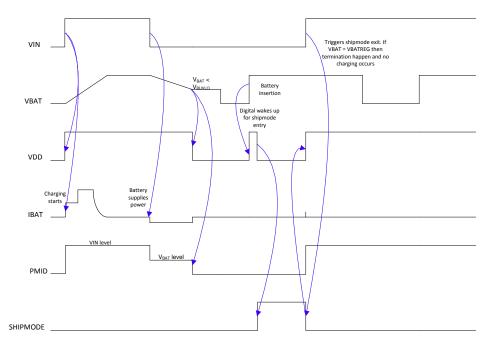


图 9-14. BQ21062 Wake-Up Upon Supply Insertion

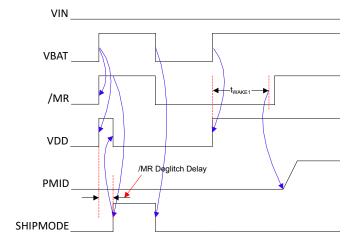


图 9-15. BQ21062 Wake-Up Upon Battery Insertion



9.5 Register Map

The device 7-bit address I²C is 0x6B (shifted 8-bit address is 0xD6).

9.5.1 I²C Registers

 $\frac{1}{2}$ 9-6 lists the memory-mapped registers for the I²C registers. All register offset addresses not listed in $\frac{1}{2}$ 9-6 should be considered as reserved locations and the register contents should not be modified.

表 9-6. I²C Registers

Address	Acronym	Register Name	Section
0x0	STAT0	Charger Status 0	Go
0x1	STAT1	Charger Status 1	Go
0x2	STAT2	Status 2	Go
0x3	FLAG0	Charger Flags 0	Go
0x4	FLAG1	Charger Flags 1	Go
0x5	FLAG2	Flags 2	Go
0x6	FLAG3	Timer Flags	Go
0x7	MASK0	Interrupt Masks 0	Go
0x8	MASK1	Interrupt Masks 1	Go
0x9	MASK2	Interrupt Masks 2	Go
0xA	MASK3	Interrupt Masks 3	Go
0x12	VBAT_CTRL	Battery Voltage Control	Go
0x13	ICHG_CTRL	Fast Charge Current Control	Go
0x14	PCHRGCTRL	Pre-Charge Current Control	Go
0x15	TERMCTRL	Termination Current Control	Go
0x16	BUVLO	Battery UVLO and Current Limit Control	Go
0x17	CHARGERCTRL0	Charger Control 0	Go
0x18	CHARGERCTRL1	Charger Control 1	Go
0x19	ILIMCTRL	Input Corrent Limit Control	Go
0x1D	LDOCTRL	LDO Control	Go
0x30	MRCTRL	MR Control	Go
0x35	ICCTRL0	IC Control 0	Go
0x36	ICCTRL1	IC Control 1	Go
0x37	ICCTRL2	IC Control 2	Go
0x40	TS_READ	TS Read	Go
0x58	TS_FAULT_MEAS	TS Fault Measurement	Go
0x61	TS_FASTCHGCTRL	TS Charge Control	Go
0x62	TS_COLD	TS Cold Threshold	Go
0x63	TS_COOL	TS Cool Threshold	Go
0x64	TS_WARM	TS Warm Threshold	Go
0x65	TS_HOT	TS Hot Threshold	Go
0x6F	DEVICE ID	Device ID	Go

Complex bit access types are encoded to fit into small table cells. $\frac{1}{2}$ 9-7 shows the codes that are used for access types in this section.

Copyright © 2023 Texas Instruments Incorporated

Product Folder Links: BQ21062

表 9-7. I²C Access Type Codes

урс то						
Access Type	Code	Description				
Read Type						
R	R	Read				
RC	C R	to Clear Read				
Write Type						
W	W	Write				
Reset or Default Value						
-n		Value after reset or the default value				

9.5.1.1 STAT0 Register (Address = 0x0) [reset = X]

STAT0 is shown in 图 9-16 and described in 表 9-8.

Return to Summary Table.

图 9-16. STAT0 Register

				•			
7	6	5	4	3	2	1	0
RESERVED	CHRG_CV_ST AT	CHARGE_DON E_STAT	IINLIM_ACTIVE _STAT	RESERVED	VINDPM_ACTI VE_STAT	THERMREG_A CTIVE_STAT	VIN_PGOOD_S TAT
R-X	R-X	R-X	R-X	R-X	R-X	R-X	R-X

表 9-8. STAT0 Register Field Descriptions

Bit	Field	Туре	Reset	Description
7	RESERVED	R	Х	Reserved
6	CHRG_CV_STAT	R	X	Constant Voltage Charging Mode (Taper Mode) Status 1b0 = Not Active 1b1 = Active
5	CHARGE_DONE_STAT	R X	Х	Charge Done Status 1b0 = Not Active 1b1 = Active
4	IINLIM_ACTIVE_STAT	R	Х	Input Current Limit Status 1b0 = Not Active 1b1 = Active
3	RESERVED	R	Х	Reserved
2	VINDPM_ACTIVE_STAT	R	Х	VINDPM Status 1b0 = Not Active 1b1 = Active
1	THERMREG_ACTIVE_ST AT	R	Х	Thermal Regulation Status 1b0 = Not Active 1b1 = Active
0	VIN_PGOOD_STAT	R	Х	VIN Power Good Status . 1b0 = Not Good 1b1 = V _{IN} > V _{UVLO} and V _{IN} > V _{BAT} + V _{SLP} and V _{IN} < V _{OVP}

Product Folder Links: BQ21062

9.5.1.2 STAT1 Register (Address = 0x1) [reset = X]

STAT1 is shown in 图 9-17 and described in 表 9-9.

Return to Summary Table.



图 9-17. STAT1 Register

7	6	5	4	3	2	1	0
VIN_OVP_FAU LT_STAT	RESERVED	BAT_OCP_FAU LT_STAT	BAT_UVLO_FA ULT_STAT	TS_COLD_STA T	TS_COOL_STA T	TS_WARM_ST AT	TS_HOT_STAT
R-X	R-X	R-X	R-X	R-X	R-X	R-X	R-X

表 9-9. STAT1 Register Field Descriptions

D:4	Pi. L.I			Descriptions
Bit	Field	Туре	Reset	Description
7	VIN_OVP_FAULT_STAT	R	X	VIN Overvoltage Status 1b0 = Not Active 1b1 = Active
6	RESERVED	R	Х	Reserved
5	BAT_OCP_FAULT_STAT	R	Х	Battery Over-Current Protection Status 1b0 = Not Active 1b1 = Active
4	BAT_UVLO_FAULT_STAT	R	Х	Battery voltage below BATUVLO Level Status 1b0 = V _{BAT} > V _{BATUVLO} 1b1 = V _{BAT} < V _{BATUVLO}
3	TS_COLD_STAT	R	Х	TS Cold Status - V _{TS} > V _{COLD} (charging suspended) 1b0 = Not Active 1b1 = Active
2	TS_COOL_STAT	R	Х	TS Cool Status - V _{COOL} < V _{TS} < V _{COLD} (charging current reduced by value set by TS_Registers) 1b0 = Not Active 1b1 = Active
1	TS_WARM_STAT	R	Х	TS Warm - V _{WARM} > V _{TS} > V _{HOT} (charging voltage reduced by value set by TS_Registers) 1b0 = Not Active 1b1 = Active
0	TS_HOT_STAT	R	Х	TS Hot Status - V _{TS} < V _{HOT} (charging suspended) 1b0 = Not Active 1b1 = Active

9.5.1.3 STAT2 Register (Address = 0x2) [reset = X]

STAT2 is shown in 图 9-18 and described in 表 9-10.

Return to Summary Table.

图 9-18. STAT2 Register

				•			
7	6	5	4	3	2	1	0
			RESERVED				TS_OPEN_STA T
R-X	R-X	R-X	R-X		R-X		R-X

表 9-10. STAT2 Register Field Descriptions

Bit	Field	Туре	Reset	Description
7-4	RESERVED	R	Х	Reserved
3-1	RESERVED	R	Х	Reserved



表 9-10. STAT2 Register Field Descriptions (continued)

Bit	Field	Туре	Reset	Description
0	TS_OPEN_STAT	R		TS Open Status $1b0 = V_{TS} < V_{OPEN}$ $1b1 = V_{TS} > V_{OPEN}$

9.5.1.4 FLAG0 Register (Address = 0x3) [reset = 0x0]

FLAG0 is shown in 图 9-19 and described in 表 9-11.

Return to Summary Table.

Clear on Read

图 9-19. FLAG0 Register

			• •				
7	6	5	4	3	2	1	0
RESERVED	CHRG_CV_FL AG	CHARGE_DON E_FLAG	IINLIM_ACTIVE _FLAG	RESERVED	VINDPM_ACTI VE_FLAG	THERMREG_A CTIVE_FLAG	VIN_PGOOD_F LAG
RC-1b0	RC-1b0	RC-1b0	RC-1b0	RC-1b0	RC-1b0	RC-1b0	RC-1b0

表 9-11. FLAG0 Register Field Descriptions

Bit	Field	Туре	Reset	Description
7	RESERVED	RC	1b0	Reserved
6	CHRG_CV_FLAG	RC	1b0	Constant Voltage Charging Mode (Taper Mode) Flag 1b0 = CV Mode Entry not detected 1b1 = CV Mode Entry detected
5	CHARGE_DONE_FLAG	RC	1b0	Charge Done Flag 1b0 = Charge Done (Termination) not detected 1b1 = Charge Done (Termination) detected
4	IINLIM_ACTIVE_FLAG	RC	1b0	Input Current Limit Flag 1b0 = Input Current Limit not detected 1b1 = Input Current Limit detected
3	RESERVED	RC	1b0	Reserved
2	VINDPM_ACTIVE_FLAG	RC	1b0	VINDPM Flag 1b0 = VINDPM operation not detected 1b1 = VIINDPM operation detected
1	THERMREG_ACTIVE_FL AG	RC	1b0	Thermal Regulation Flag 1b0 = Thermal Regulation not detected 1b1 = Thermal Regulation detected
0	VIN_PGOOD_FLAG	RC	1b0	VIN Power Good Flag . Interrupt will not be sent if device powers up with VIN_PGOOD condition and V _{BAT} < V _{BATUVLO} 1b0 = No change in VIN Power Good Status 1b1 = Change in VIN Power Good Status detected.

9.5.1.5 FLAG1 Register (Address = 0x4) [reset = 0x0]

FLAG1 is shown in 图 9-20 and described in 表 9-12.

Return to Summary Table.

Clear on Read

图 9-20. FLAG1 Register





图 9-20. FLAG1 Register (continued)

VIN_OVP_FAU LT_FLAG	RESERVED	BAT_OCP_FAU LT_FLAG	BAT_UVLO_FA ULT_FLAG	TS_COLD_FLA G	TS_COOL_FLA G	TS_WARM_FL AG	TS_HOT_FLAG	
RC-1b0	RC-1b0	RC-1b0	RC-1b0	RC-1b0	RC-1b0	RC-1b0	RC-1b0	

表 9-12. FLAG1 Register Field Descriptions

Bit	Field	Туре	Reset	Description
7	VIN_OVP_FAULT_FLAG	RC	1b0	VIN Over Voltage Fault Flag 1b0 = No overvoltage condition detected 1b1 = VIN overvoltage condition detected
6	RESERVED	RC	1b0	Reserved
5	BAT_OCP_FAULT_FLAG	RC	1b0	Battery Over Current Protection Flag 1b0 = No Battery Over Current condition detected 1b1 = Battery Over Current condition detected
4	BAT_UVLO_FAULT_FLAG	RC	1b0	Battery Under Voltage Flag 1b0 = Battery below BATUVLO condition detected 1b1 = No Battery below BATUVLO condition detected
3	TS_COLD_FLAG	RC	1b0	TS Cold Region Entry Flag 1b0 = TS Cold Region Entry not detected 1b1 = TS Cold Region Entry detected
2	TS_COOL_FLAG	RC	1b0	TS Cool Region Entry Flag 1b0 = TS Cool Region Entry not detected 1b1 = TS Co0l Region Entry detected
1	TS_WARM_FLAG	RC	1b0	TS Warm Region Entry Flag 1b0 = TS Warm Region Entry not detected 1b1 = TS Warm Region Entry detected
0	TS_HOT_FLAG	RC	1b0	TS Hot Region Entry Flag 1b0 = TS Hot Region Entry not detected 1b1 = TS Hot Region Entry detected

9.5.1.6 FLAG2 Register (Address = 0x5) [reset = 0x0]

FLAG2 is shown in 图 9-21 and described in 表 9-13.

Return to Summary Table.

Submit Document Feedback

Clear on Read

图 9-21. FLAG2 Register

	7	6	5	4	3	2	1	0
				RESERVED				TS_OPEN_FLA
								G
	RC-1b0	RC-1b0	RC-1b0	RC-1b0		RC-3b000		RC-1b0
- 1								

表 9-13. FLAG2 Register Field Descriptions

Bit	Field	Туре	Reset	Description
7-4	RESERVED	R	X	Reserved
3-1	RESERVED	RC	3b000	Reserved
0	TS_OPEN_FLAG	RC	1b0	TS Open Flag 1b0 = No TS Open fault detected 1b1 = TS Open fault detected

9.5.1.7 FLAG3 Register (Address = 0x6) [reset = 0x0]

FLAG3 is shown in 图 9-22 and described in 表 9-14.

Return to Summary Table.

Clear on Read

图 9-22. FLAG3 Register

7	6	5	4	3	2	1	0
RESERVED	WD_FAULT_FL AG	SAFETY_TMR_ FAULT_FLAG	LDO_OCP_FA ULT_FLAG	RESERVED	MRWAKE1_TI MEOUT_FLAG		MRRESET_WA RN_FLAG
RC-1b0	RC-1b0	RC-1b0	RC-1b0	RC-1b0	RC-1b0	RC-1b0	RC-1b0

表 9-14. FLAG3 Register Field Descriptions

Bit	Field	Туре	Reset	Description
7	RESERVED	RC	1b0	Reserved
6	WD_FAULT_FLAG	RC	1b0	Watchdog Fault Flag 1b0 = Watchdog Timer not expired 1b1 = Watchdog Timer expired
5	SAFETY_TMR_FAULT_F LAG	RC	1b0	Safety Timer Fault Flag 1b0 = Safety Timer not expired 1b1 = Safety Timer Expired
4	LDO_OCP_FAULT_FLAG	RC	1b0	LDO Over Current Fault 1b0 = LDO Normal 1b1 = LDO Over current fault detected
2	MRWAKE1_TIMEOUT_FL AG	RC	1b0	MR Wake 1 Timer Flag 1b0 = MR Wake 1 timer not expired 1b1 = MR Wake 1 timer expired
1	MRWAKE2_TIMEOUT_FL AG	RC	1b0	MR Wake 2 Timer Flag 1b0 = MR Wake 2 timer not expired 1b1 = MR Wake 2 timer expired
0	MRRESET_WARN_FLAG	RC	1b0	MR Reset Warn Timer Flag 1b0 = MR Reset Warn timer not expired 1b1 = MR Reset Warn timer expired

9.5.1.8 MASK0 Register (Address = 0x7) [reset = 0x0]

MASK0 is shown in 图 9-23 and described in 表 9-15.

Return to Summary Table.

图 9-23. MASK0 Register

7	6	5	4	3	2	1	0
RESERVED	CHRG_CV_MA SK	CHARGE_DON E_MASK	IINLIM_ACTIVE _MASK	RESERVED	VINDPM_ACTI VE_MASK	THERMREG_A CTIVE_MASK	VIN_PGOOD_ MASK
R/W-1b0	R/W-1b0	R/W-1b0	R/W-1b0	R/W-1b0	R/W-1b0	R/W-1b0	R/W-1b0

表 9-15. MASK0 Register Field Descriptions

Bit	Field	Туре	Reset	Description
7	RESERVED	R/W	1b0	Reserved 1b0 = Interrupt Not Masked 1b1 = Interrupt Masked

Product Folder Links: BQ21062

Copyright © 2023 Texas Instruments Incorporated

Submit Document Feedback

37



表 9-15. MASK0 Register Field Descriptions (continued)

Bit	Field	Туре	Reset	Description
6	CHRG_CV_MASK	R/W	1b0	Mask for CHRG_CV interrupt 1b0 = Interrupt Not Masked 1b1 = Interrupt Masked
5	CHARGE_DONE_MASK	R/W	1b0	Mask for CHARGE_DONE interrupt 1b0 = Interrupt Not Masked 1b1 = Interrupt Masked
4	IINLIM_ACTIVE_MASK	R/W	1b0	Mask for IINLIM_ACTIVE interrupt 1b0 = Interrupt Not Masked 1b1 = Interrupt Masked
3	RESERVED	R/W	1b0	Reserved
2	VINDPM_ACTIVE_MASK	R/W	1b0	Mask for VINDPM_ACTIVE interrupt 1b0 = Interrupt Not Masked 1b1 = Interrupt Masked
1	THERMREG_ACTIVE_M ASK	R/W	1b0	Mask for THERMREG_ACTIVE interrupt 1b0 = Interrupt Not Masked 1b1 = Interrupt Masked
0	VIN_PGOOD_MASK	R/W	1b0	Mask for VIN_PGOOD interrupt 1b0 = Interrupt Not Masked 1b1 = Interrupt Masked

9.5.1.9 MASK1 Register (Address = 0x8) [reset = 0x0]

MASK1 is shown in 图 9-24 and described in 表 9-16.

Return to Summary Table.

图 9-24. MASK1 Register



表 9-16. MASK1 Register Field Descriptions

Bit	Field	Туре	Reset	Description		
7	VIN_OVP_FAULT_MASK	R/W	1b0	Mask for VIN_OVP_FAULT interrupt 1b0 = Interrupt Not Masked		
				1b1 = Interrupt Masked		
6	RESERVED	R/W	1b0	Reserved		
5	BAT_OCP_FAULT_MASK	R/W	160	Mask for BAT_OCP_FAULT interrupt 1b0 = Interrupt Not Masked 1b1 = Interrupt Masked		
4	BAT_UVLO_FAULT_MAS	R/W	1b0	Mask for BAT_UVLO_FAULT interrupt 1b0 = Interrupt Not Masked 1b1 = Interrupt Masked		
3	TS_COLD_MASK	R/W	1b0	Mask for TS_COLD interrupt 1b0 = Interrupt Not Masked 1b1 = Interrupt Masked		
2	TS_COOL_MASK	R/W	1b0	Mask for TS_COOL interrupt 1b0 = Interrupt Not Masked 1b1 = Interrupt Masked		

Product Folder Links: BQ21062

Submit Document Feedback

Copyright © 2023 Texas Instruments Incorporated

表 9-16. MASK1 Register Field Descriptions (continued)

Bit	Field	Туре	Reset	Description							
1	TS_WARM_MASK	R/W	1b0	Mask for TS_WARM interrupt 1b0 = Interrupt Not Masked 1b1 = Interrupt Masked							
0	TS_HOT_MASK	R/W	160	Mask for TS_HOT interrupt 1b0 = Interrupt Not Masked 1b1 = Interrupt Masked							

9.5.1.10 MASK2 Register (Address = 0x9) [reset = 0x71]

MASK2 is shown in 图 9-25 and described in 表 9-17.

Return to Summary Table.

图 9-25. MASK2 Register



表 9-17. MASK2 Register Field Descriptions

Bit	Field	Туре	Reset	Description
7	RESERVED	R	X	Reserved
6	RESERVED	R	X	Reserved
5	RESERVED	R	Х	Reserved
4	RESERVED	R	Х	Reserved
3-1	RESERVED	R/W	3b000	Reserved
0	TS_OPEN_MASK	R/W	1b1	Mask for TS_OPEN Interrupt 1b0 = Interrupt Not Masked 1b1 = Interrupt Masked

9.5.1.11 MASK3 Register (Address = 0xA) [reset = 0x0]

MASK3 is shown in 图 9-26 and described in 表 9-18.

Return to Summary Table.

图 9-26. MASK3 Register

7	6	5	4	3	2	1	0
RESERVED	WD_FAULT_M ASK	SAFETY_TMR_ FAULT_MASK	LDO_OCP_FA ULT_MASK	RESERVED	MRWAKE1_TI MEOUT_MASK	MRWAKE2_TI MEOUT_MASK	MRRESET_WA RN_MASK
R/W-1b0	R/W-1b0	R/W-1b0	R/W-1b0	R/W-1b0	R/W-1b0	R/W-1b0	R/W-1b0

表 9-18. MASK3 Register Field Descriptions

Bit	Field	Туре	Reset	Description	
7	RESERVED	R/W	1b0	Reserved	
6	WD_FAULT_MASK	R/W	1b0	Mask for WD_FAULT Interrupt 1b0 = Interrupt Not Masked 1b1 = Interrupt Masked	



表 9-18. MASK3 Register Field Descriptions (continued)

Bit	Field	Туре	Reset	Description
5	SAFETY_TMR_FAULT_M ASK	R/W	1b0	Mask for SAFETY_TIMER_FAULT Interrupt 1b0 = Interrupt Not Masked 1b1 = Interrupt Masked
4	LDO_OCP_FAULT_MASK	R/W	1b0	Mask for LDO_OCP_FAULT Interrupt 1b0 = Interrupt Not Masked 1b1 = Interrupt Masked
3	RESERVED	R/W	1b0	Reserved
2	MRWAKE1_TIMEOUT_M ASK	R/W	1b0	Mask for MRWAKE1_TIMEOUT Interrupt 1b0 = Interrupt Not Masked 1b1 = Interrupt Masked
1	MRWAKE2_TIMEOUT_M ASK	R/W	1b0	Mask for MRWAKE2_TIMEOUT Interrupt 1b0 = Interrupt Not Masked 1b1 = Interrupt Masked
0	MRRESET_WARN_MASK	R/W	1b0	Mask for MRRESET_WARN Interrupt 1b0 = Interrupt Not Masked 1b1 = Interrupt Masked

9.5.1.12 VBAT_CTRL Register (Address = 0x12) [reset = 0x3C]

VBAT_CTRL is shown in 图 9-27 and described in 表 9-19.

Return to Summary Table.

图 9-27. VBAT_CTRL Register

			_				
7	6	5	4	3	2	1	0
RESERVED				VBAT_REG_6:0			
R/W-1b0				R/W-7b0111100			

表 9-19. VBAT_CTRL Register Field Descriptions

	Bit Field Type			Reset	Description
İ	7 RESERVED R/W 1b0		1b0	Reserved	
	6-0	VBAT_REG_6:0	R/W	7b0111100	Battery Regulation Voltage (4.2 V default) VBATREG = 3.6 V + VBAT_REG code x 10 mV If a value greater than 4.6 V is written, the setting will go to 4.6 V

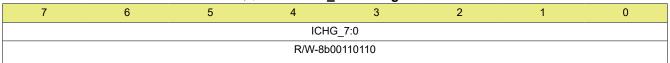
9.5.1.13 ICHG_CTRL Register (Address = 0x13) [reset = 0x36]

ICHG_CTRL is shown in 图 9-28 and described in 表 9-20.

Return to Summary Table.

Submit Document Feedback

图 9-28. ICHG_CTRL Register



Product Folder Links: BQ21062

表 9-20. ICHG CTRL Register Field Descriptions

Bit	Field	Туре	Reset	Description
7-0	ICHG_7:0	R/W		Fast Charge Current (67.5 mA default) Fast Charge Current = 1.25 mA x ICHG code (ICHARGE_RANGE = 0) Fast Charge Current = 2.5 mA x ICHG code (ICHARGE_RANGE = 1)

9.5.1.14 PCHRGCTRL Register (Address = 0x14) [reset = 0x7]

PCHRGCTRL is shown in 图 9-29 and described in 表 9-21.

Return to Summary Table.

图 9-29. PCHRGCTRL Register

		-		- 3	-		
7	6	5	4	3	2	1	0
ICHARGE_RAN GE	RESE	RVED			IPRECHG_4:0		
R/W-1b0	R/W	-2b00			R/W-5b00111		

表 9-21. PCHRGCTRL Register Field Descriptions

Bit	Field	Туре	Reset	Description
7	ICHARGE_RANGE	1b0 = 1.25 mA step (318.75 mA max charge		Charge Current Step 1b0 = 1.25 mA step (318.75 mA max charge current) 1b1 = 2.5 mA step (500 mA max charge current)
6-5	RESERVED	R/W	2b00	Reserved
4-0	IPRECHG_4:0	R/W	5b00111	Pre-Charge Current (8.75 mA default) Pre-Charge Current = 1.25 mA x IPRECHG code (ICHARGE_RANGE = 0) Pre-Charge Current = 2.5 mA x IPRECHG code (ICHARGE_RANGE = 1)

9.5.1.15 TERMCTRL Register (Address = 0x15) [reset = 0x14]

TERMCTRL is shown in 图 9-30 and described in 表 9-22.

Return to Summary Table.

图 9-30. TERMCTRL Register

		-	•	- 3			
7	6	5	4	3	2	1	0
RESER	VED			ITERM_4:0			TERM_DISABL E
R/W-2	b00			R/W-5b01010			R/W-1b0

表 9-22. TERMCTRL Register Field Descriptions

Bit	Field	Туре	Reset	Description
7-6	RESERVED	R/W	2b00	Reserved



表 9-22. TERMCTRL Register Field Descriptions (continued)

Bit	Field	Туре	Reset	Description
5-1	ITERM_4:0	R/W	5b01010	Termination Current (10% of ICHRG default) Programmable Range = 1% to 31% of ICHRG 5b00000 = Do not Use 5b00001 = 1% of ICHRG 5b00010 = 2% of ICHRG 5b00100 = 4% of ICHRG 5b01000 = 8% of ICHRG 5b10000 = 16% of ICHRG
0	TERM_DISABLE	R/W	1b0	Termination Disable 1b0 = Termination Enabled 1b1 = Termination Disabled

9.5.1.16 BUVLO Register (Address = 0x16) [reset = 0x3]

BUVLO is shown in 图 9-31 and described in 表 9-23.

Return to Summary Table.

图 9-31. BUVLO Register

7	6	5	4	3	2	1	0
RESE	RVED	VLOWV_SEL	IBAT_OCF	P_ILIM_1:0		BUVLO_2:0	
R/W-	2b00	R/W-1b0	R/W-	-2b00		R/W-3b011	

表 9-23. BUVLO Register Field Descriptions

Bit	Field	Туре	Reset	Description
7-6	RESERVED	R/W	2b00	Reserved
5	VLOWV_SEL	R/W	1b0	Pre-charge to Fast Charge Threshold 1b0 = 3.0 V 1b1 = 2.8 V
4-3	IBAT_OCP_ILIM_1:0	R/W	Battery Over-Current Protection Threshold 2b00 = 1200 mA 2b01 = 1500 mA 2b10 = Disabled 2b11 = Disabled	
2-0	BUVLO_2:0	R/W	3b011	Battery UVLO Voltage 3b000 = 3.0 V 3b001 = 3.0 V 3b010 = 3.0 V 3b011 = 2.8 V 3b100 = 2.6 V 3b101 = 2.4 V 3b110 = 2.2 V 3b111 = Disabled

9.5.1.17 CHARGERCTRL0 Register (Address = 0x17) [reset = 0x92]

CHARGERCTRL0 is shown in 图 9-32 and described in 表 9-24.

Return to Summary Table.

Submit Document Feedback

Product Folder Links: BQ21062

图 9-32. CHARGERCTRL0 Register

7	6	5	4	3	2	1	0
TS_EN	TS_CONTROL _MODE	VRH_THRESH	WATCHDOG_D ISABLE	2XTMR_EN	SAFETY_TIME	ER_LIMIT_1:0	RESERVED
R/W-1b1	R/W-1b0	R/W-1b0	R/W-1b1	R/W-1b0	R/W-2	2b01	R/W-1b0

表 9-24. CHARGERCTRL0 Register Field Descriptions

Bit	Field	Туре	Reset	Description
7	TS_EN	R/W	TS Function Enable 1b0 = TS function disabled (Only charge control is disabled. TS_OPEN detection and TS ADC monitoring remain enabled) 1b1 = TS function enabled	
6	TS_CONTROL_MODE	R/W	1b0	TS Function Control Mode 1b0 = Custom (JEITA) 1b1 = Disable charging on HOT/COLD Only
5	VRH_THRESH	R/W	1b0 Recharge Voltage Threshold 1b0 = 140 mV 1b1 = 200 mV	
4	WATCHDOG_DISABLE	R/W	1b1	Watchdog Timer Disable 1b0 = Watchdog timer enabled 1b1 = Watchdog timer disabled
3	2XTMR_EN	R/W	1b0	Enable 2X Safety Timer 1b0 = The timer is not slowed at any time 1b1 = The timer is slowed by 2x when in any control other than CC or CV
2-1	SAFETY_TIMER_LIMIT_1:0	R/W	2b01	Charger Safety Timer 2b00 = 3 Hr Fast Charge 2b01 = 6 Hr Fast Charge 2b10 = 12 Hr Fast Charge 2b11 = Disabled
0	RESERVED	R/W	1b0	Reserved

9.5.1.18 CHARGERCTRL1 Register (Address = 0x18) [reset = 0x32]

CHARGERCTRL1 is shown in 图 9-33 and described in 表 9-25.

Return to Summary Table.

图 9-33. CHARGERCTRL1 Register

7	6	5	4	3	2	1	0
VINDPM_DIS		VINPDM_2:0		RESERVED		THERM_REG_2:	0
R/W-1b0		R/W-3b011		R/W-1b1		R/W-3b010	

表 9-25. CHARGERCTRL1 Register Field Descriptions

_					9
	Bit	Field Type Reset		Reset	Description
	7	VINDPM_DIS	R/W	1b0	Disable VINDPM Function
					1b0 = VINDPM Enabled
					1b1 = VINDPM Disabled



表 9-25. CHARGERCTRL1 Register Field Descriptions (continued)

Field	Туре	Reset	Description
VINPDM_2:0	R/W	3b011	VINDPM Level Selection
			3b000 = 4.2 V
			3b001 = 4.3 V
			3b010 = 4.4 V
			3b011 = 4.5 V
			3b100 = 4.6 V
			3b101 = 4.7 V
			3b110 = 4.8 V
			3b111 = 4.9 V
RESERVED	R/W	1b1	Reserved
THERM_REG_2:0	R/W	3b010	Thermal Charge Current Foldback Threshold
			3b000 = 80°C
			3b001 = 85°C
			3b010 = 90°C
			3b011 = 95°C
			3b100 = 100°C
			3b101 = 105°C
			3b110 = 110°C
			3b111 = Disabled
	VINPDM_2:0	VINPDM_2:0 R/W RESERVED R/W	VINPDM_2:0 R/W 3b011 RESERVED R/W 1b1

9.5.1.19 ILIMCTRL Register (Address = 0x19) [reset = 0x1]

ILIMCTRL is shown in 图 9-34 and described in 表 9-26.

Return to Summary Table.

图 9-34. ILIMCTRL Register



表 9-26. ILIMCTRL Register Field Descriptions

Bit	Field	Туре	Reset	Description
7-3	RESERVED	R/W	5b00000	Reserved
2-0	ILIM_2:0	R/W	3b001	Input Current Limit Level Selection 3b000 = 50 mA 3b001 = 100 mA 3b010 = 150 mA 3b011 = 200 mA 3b100 = 300 mA 3b101 = 400 mA 3b110 = 500 mA 3b111 = 600 mA

9.5.1.20 LDOCTRL Register (Address = 0x1D) [reset = 0x32]

LDOCTRL is shown in 图 9-35 and described in 表 9-27.

Return to Summary Table.

图 9-35. LDOCTRL Register

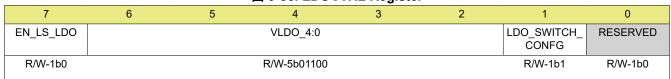


表 9-27. LDOCTRL Register Field Descriptions

Bit	Field	Туре	Reset	Description
7	EN_LS_LDO R/W 1b0		1b0	LS/LDO Enable 1b0 = Disable LS/LDO
		1b1 = Enable LS/LDO		1b1 = Enable LS/LDO
6-2	VLDO_4:0	R/W	5b01100	LDO output voltage setting (1.8 V default) LDO Voltage = 600 mV + VLDO Code x 100 mV
1	LDO_SWITCH_CONFG	R/W	1b1	LDO / Load Switch Configuration Select 1b0 = LDO 1b1 = Load Switch
0	RESERVED	R/W	1b0	Reserved

Product Folder Links: BQ21062

9.5.1.21 MRCTRL Register (Address = 0x30) [reset = 0x2E]

MRCTRL is shown in 图 9-36 and described in 表 9-28.

Return to Summary Table.



图 9-36. MRCTRL Register

7	6	5	4	3	2	1	0
MR_RESET_VI N	MR_WAKE1_TI MER	MR_WAKE2_TI MER	MR_RESET_	_WARN_1:0	MR_HW_R	ESET_1:0	RESERVED
R/W-1b0	R/W-1b0	R/W-1b1	R/W-2	2b01	R/W-	2b11	R/W-1b0

表 9-28. MRCTRL Register Field Descriptions

Bit	Field	Туре	Reset	Description
7	MR_RESET_VIN	R/W	1b0	VIN Power Good gated MR Reset Enable 1b0 = Reset sent when /MR reset time is met regardless of VIN state 1b1 = Reset sent when MR reset is met and Vin is valid
6	MR_WAKE1_TIMER	R/W	1b0	Wake 1 Timer setting 1b0 = 125 ms 1b1 = 500 ms
5	MR_WAKE2_TIMER	R/W	1b1	Wake 2 Timer setting 1b0 = 1 s 1b1 = 2 s
4-3	MR_RESET_WARN_1:0	R/W	2b01	MR Reset Warn Timer setting 2b00 = MR_HW_RESET - 0.5 s 2b01 = MR_HW_RESET - 1.0 s 2b10 = MR_HW_RESET - 1.5 s 2b11 = MR_HW_RESET - 2.0 s
2-1	MR_HW_RESET_1:0	R/W	2b11	MR HW Reset Timer setting 2b00 = 4 s 2b01 = 8 s 2b10 = 10 s 2b11 = 14 s
0	RESERVED	R/W	1b0	Reserved

9.5.1.22 ICCTRL0 Register (Address = 0x35) [reset = 0x20]

ICCTRL0 is shown in 图 9-37 and described in 表 9-29.

Return to Summary Table.

图 9-37. ICCTRL0 Register

7	6	5	4	3	2	1	0
EN_SHIP_MOD E	RESERVED	AUTOWAKE_1:0		RESERVED	GLOBAL_INT_ MASK	HW_RESET	SW_RESET
R/W-1b0	R/W-1b0	R/W-	2b10	R/W-1b0	R/W-1b0	R/W-1b0	R/W-1b0

表 9-29. ICCTRL0 Register Field Descriptions

Bit	Field	Туре	Reset	Description
7	EN_SHIP_MODE	R/W	1b0	Ship Mode Enable
		1b0 = Normal operation		1b0 = Normal operation
				1b1 = Enter Ship Mode when VIN is not valid and /MR is high
6	RESERVED	R/W	1b0	Reserved
5-4	AUTOWAKE_1:0	VAKE_1:0 R/W 2b10 Auto-wakeup Timer (TRESTART) for		Auto-wakeup Timer (TRESTART) for /MR HW Reset
				2b00 = 0.6 s
				2b01 = 1.2 s
				2b10 = 2.4 s
				2b11 = 5 s

Product Folder Links: BQ21062

Submit Document Feedback

Copyright © 2023 Texas Instruments Incorporated

表 9-29. ICCTRL0 Register Field Descriptions (continued)

Bit	Field	Туре	Reset	Description		
3	RESERVED	R/W	1b0	Reserved		
2	GLOBAL_INT_MASK	AL_INT_MASK R/W 1b0 Global Interrupt Mask 1b0 = Normal Operation 1b1 = Mask all interrupts		1b0 = Normal Operation		
1	HW_RESET	R/W	1b0	HW Reset 1b0 = Normal operation 1b1 = HW Reset. Temporarily power down all power rails, except VDD. I ² C Register go to default settings.		
0	SW_RESET	R/W	1b0	SW_Reset 1b0 = Normal operation 1b1 = SW Reset. I ² C Registers go to default settings.		

9.5.1.23 ICCTRL1 Register (Address = 0x36) [reset = 0x0]

ICCTRL1 is shown in 图 9-38 and described in 表 9-30.

Return to Summary Table.

图 9-38. ICCTRL1 Register

7 6 5 4 3 2 1	0
MR_LPRESS_ACTION_1:0 RESERVED RESERVED PG_MODE_1:0 P	PMID_MODE_1:0
R/W-2b00 R/W-1b0 R/W-1b0 R/W-2b00	R/W-2b00

表 9-30. ICCTRL1 Register Field Descriptions

Bit	Field	Туре	Reset	Description
7-6	MR_LPRESS_ACTION_1:	R/W	2b00	MR Long Press Action 2b00 = HW Reset (Power Cycle) 2b01 = Do nothing 2b10 = Enter Ship Mode 2b11 = Enter Ship Mode
5	RESERVED	R/W	1b0	Reserved
4	RESERVED	R/W	1b0	Reserved
3-2	PG_MODE_1:0	R/W	2600	\overline{PG} Pin Mode of Operation 2b00 = VIN Power Good. \overline{PG} pulls to GND when $V_{IN} > V_{UVLO}, V_{IN} > V_{BAT} + V_{SLP}$ and $V_{IN} < V_{IN_OVP}.$ 2b01 = Deglitched Level Shifted /MR. \overline{PG} is high impedance when the \overline{MR} input is high, and \overline{PG} pulls to GND when the \overline{MR} input is low. 2b1x = General Purpose Open Drain Output. The state of the \overline{PG} pin is then controlled through the GPO_PG bit, where if GPO_PG is 0 , the \overline{PG} pin is pulled to GND and if it is 1, the \overline{PG} pin is in high impedance.
1-0	PMID_MODE_1:0	R/W	2b00	PMID Control Sets how PMID is powered in any state, except Ship Mode. 2b00 = PMID powered from BAT or VIN if present 2b01 = PMID powered from BAT only, even if VIN is present 2b10 = PMID disconnected and left floating 2b11 = PMID disconnected and pulled down.



9.5.1.24 ICCTRL2 Register (Address = 0x37) [reset = 0x40]

ICCTRL2 is shown in 图 9-39 and described in 表 9-31.

Return to Summary Table.

图 9-39. ICCTRL2 Register

7	6	5	4	3	2	1	0
F	PMID_REG_CTRL_2:0)	GPO_PG	RESE	RVED	HWRESET_14 S_WD	CHARGER_DIS ABLE
	R/W-3b010		R/W-1b0	R/W-	2b00	R/W-1b0	R/W-1b0

表 9-31. ICCTRL2 Register Field Descriptions

Bit	Field	Туре	Reset	Description
7-5	PMID_REG_CTRL_2:0	R/W	3b010	System (PMID) Regulation Voltage 3b000 = Battery Tracking
				3b001 = 4.4 V
				3b010 = 4.5 V
				3b011 = 4.6 V
				3b100 = 4.7 V
				3b101 = 4.8 V
				3b110 = 4.9 V
				3b111 = Pass-Through (V _{IN})
4	GPO_PG	R/W	1b0	/PG General Purpose Output State Control
				1b0 = Pulled Down
				1b1 = High Z
3-2	RESERVED	R/W	2b00	Reserved
1	HWRESET_14S_WD	R/W	1b0	Enable for 14-second I ² C watchdog timer for HW Reset after VIN connection
				1b0 = Timer disabled
				1b1 = Device will perform HW reset if no I ² C transaction is done
				within 14 s after VIN is present
0	CHARGER_DISABLE	R/W	1b0	Charge Disable
				1b0 = Charge enabled if /CE pin is low
				1b1 = Charge disabled

$9.5.1.25 \text{ TS}_{READ} \text{ Register (Address = 0x40) [reset = 0x2]}$

TS_Read is shown in 图 9-40 and described in 表 9-32.

Return to Summary Table.

图 9-40. TS_READ Register

7	6	5	4	3	2	1	0
INTERVAL	RESERVED	GET_FAULT_ENABLE	RESE	RVED		RESERVED)
R/W-1b0	R-1b0	R/W-1b0	R/W-	2b00		R/W-3b010	

表 9-32. TS_READ Register Field Descriptions

Bit	Field	Туре	Reset	Description
7	INTERVAL	R/W		Interval rate for TS read in BAT Only operation 1b0 = Manual Read (TS pin checked when GET_FAULT_ENABLE is set) 1b1 = TS pin checked every 1 second

Product Folder Links: BQ21062

Submit Document Feedback

Copyright © 2023 Texas Instruments Incorporated

表 9-32. TS READ Register Field Descriptions (continued)

	* 0 02. TO_KEAD Register Field Descriptions (continued)								
Bit	Field	Туре	Reset	Description					
6	RESERVED	R/W	1b0	Reserved					
5	GET_FAULT_ENABLE	R/W	1b0	TS Fault Read Trigger. Bit goes back to 0 when read is complete 1b0 = Normal Operation 1b1 = Initiate TS Fault read					
4-3	RESERVED	R/W	2b00	Reserved					
2-0	RESERVED	R/W	3b010	Reserved					

9.5.1.26 TS_FAULT_MEAS Register (Address = 0x58) [reset = 0x0]

TS_FAULT_MEAS is shown in 图 9-41 and described in 表 9-33.

Return to Summary Table.

图 9-41. TS_FAULT_MEAS Register

7	6	5	4	3	2	1	0
Reserved	Reserved	Reserved	Reserved	Reserved	Fault_Enable	Reserved	Reserved
R/W-1b0	R/W-1b0	R/W-1b0	R/W-1b0	R/W- 1b0	R/W-1b0	R/W-1b0	R/W-1b0

表 9-33. TS_Fault_MEAS Register Field Descriptions

Bit	Field	Туре	Reset	Description
7	RESERVED	R/W	1b0	Reserved
6	RESERVED	R/W	1b0	Reserved
5	RESERVED	R/W	1b0	Reserved
4	RESERVED	R/W	1b0	Reserved
3	RESERVED	R/W	1b0	Reserved
2	TS_FAULT_MEAS_ENABLE	R/W	160	Enable TS Fault Measurement 1b0 = Measurement disabled 1b1 = Measurement enabled
1	RESERVED	R/W	1b0	Reserved
0	RESERVED	R/W	1b0	Reserved

9.5.1.27 TS_FASTCHGCTRL Register (Address = 0x61) [reset = 0x34]

TS_FASTCHGCTRL is shown in 图 9-42 and described in 表 9-34.

Return to Summary Table.

图 9-42. TS_FASTCHGCTRL Register

7	6	5	4	3	2	1	0
RESERVED	٦	S_VBAT_REG2:	0	RESERVED		TS_ICHRG_2:0	
R/W-1b0		R/W-3b011		R/W-1b0		R/W-3b100	

表 9-34. TS_FASTCHGCTRL Register Field Descriptions

Bit	Field	Туре	Reset	Description
7	RESERVED	R/W	1b0	Reserved

Product Folder Links: BQ21062

Copyright © 2023 Texas Instruments Incorporated

Submit Document Feedback



表 9-34. TS_FASTCHGCTRL Register Field Descriptions (continued)

Bit	Field	Туре	Reset	Description
6-4	TS_VBAT_REG2:0	R/W	3b011	Reduced target battery voltage during Warm
				3b000 = No reduction
				3b001 = VBAT_REG - 50 mV
				3b010 = VBAT_REG - 100 mV
				3b011 = VBAT_REG - 150 mV
				3b100 = VBAT_REG - 200 mV
				3b101 = VBAT_REG - 250 mV
				3b110 = VBAT_REG - 300 mV
				3b111 = VBAT_REG - 350 mV
3	RESERVED	R/W	1b0	Reserved
2-0	TS_ICHRG_2:0	R/W	3b100	Fast charge current when decreased by TS function
				3b000 = No reduction
				3b001 = 0.875 x ICHG
				3b010 = 0.750 x ICHG
				3b011 = 0.625 x ICHG
				3b100 = 0.500 x ICHG
				3b101 = 0.375 x ICHG
				3b110 = 0.250 x ICHG
				3b111 = 0.125 x ICHG

$9.5.1.28 \text{ TS_COLD Register}$ (Address = 0x62) [reset = 0x7C]

TS_COLD is shown in $\[\]$ 9-43 and described in 表 9-35.

Return to Summary Table.

图 9-43. TS_COLD Register



表 9-35. TS_COLD Register Field Descriptions

Bit	Field	Туре	Reset	Description
7-0	TS_COLD_7:0	R/W	8b01111100	TS Cold Threshold
				1b = 4.688 mV
				10b = 9.375 mV
				100b = 18.75 mV
				1000b = 37.5 mV
				10000b = 75 mV
				100000b = 150 mV
				1000000b = 300 mV
				10000000b = 600 mV

Product Folder Links: BQ21062

English Data Sheet: SLUSE42

Submit Document Feedback

9.5.1.29 TS_COOL Register (Address = 0x63) [reset = 0x6D]

TS_COOL is shown in 图 9-44 and described in 表 9-36.

Return to Summary Table.

图 9-44. TS_COOL Register



表 9-36. TS_COOL Register Field Descriptions

Bit	Field	Туре	Reset	Description
7-0	TS_COOL_7:0	R/W	8b01101101	TS Cool Threshold 1b = 4.688 mV 10b = 9.375 mV 100b = 18.75 mV 1000b = 37.5 mV 10000b = 75 mV
				100000b = 150 mV 1000000b = 300 mV 10000000b = 600 mV

$9.5.1.30 \text{ TS}_WARM \text{ Register (Address} = 0x64) [reset = 0x38]$

TS_WARM is shown in 图 9-45 and described in 表 9-37.

Return to Summary Table.

图 9-45. TS_WARM Register



表 9-37. TS_WARM Register Field Descriptions

Bit	Field	Туре	Reset	Description
7-0	TS_WARM_7:0	R/W	8b00111000	TS Warm Threshold
				1b = 4.688 mV
				10b = 9.375 mV
				100b = 18.75 mV
				1000b = 37.5 mV
				10000b = 75 mV
				100000b = 150 mV
				1000000b = 300 mV
				10000000b = 600 mV



$9.5.1.31 \text{ TS}_{HOT} \text{ Register (Address = 0x65) [reset = 0x38]}$

TS_HOT is shown in 图 9-46 and described in 表 9-38.

Return to Summary Table.

图 9-46. TS_HOT Register

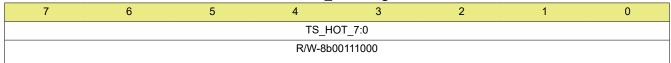


表 9-38. TS_HOT Register Field Descriptions

Bit	Field	Туре	Reset	Description
7-0	TS_HOT_7:0	R/W		TS Hot Threshold 1b = 4.688 mV 10b = 9.375 mV 100b = 18.75 mV 1000b = 37.5 mV 10000b = 75 mV 100000b = 150 mV 1000000b = 300 mV
				10000000b = 600 mV

9.5.1.32 DEVICE_ID Register (Address = 0x6F) [reset = 0x3B]

DEVICE_ID is shown in 图 9-47 and described in 表 9-39.

Return to Summary Table.

图 9-47. DEVICE_ID Register



表 9-39. DEVICE_ID Register Field Descriptions

	Bit	Field	Туре	Reset	Description
Γ	7-0	DEVICE_ID_7:0	R	8b00111011	Device ID
					00111011b = BQ21062

Copyright © 2023 Texas Instruments Incorporated Product Folder Links: *BQ21062*



10 Application and Implementation

备注

以下应用部分中的信息不属于 TI 器件规格的范围, TI 不担保其准确性和完整性。TI 的客户应负责确定器件是否适用于其应用。客户应验证并测试其设计,以确保系统功能。

10.1 Application Information

A typical application of the BQ21062 consists of the device configured as an I²C controlled single cell Li-ion battery charger and power path manager or small battery applications such as smart-watches and wireless headsets. A battery thermistor may be connected to the TS pin to allow the device to monitor the battery temperature and control charging as desired.

The system designer may connect the $\overline{\text{MR}}$ input to a push-button to send interrupts to the host as the button is pressed or to allow the application's end user to reset the system. If not used this pin must be left floating or tied to BAT.

10.2 Typical Application

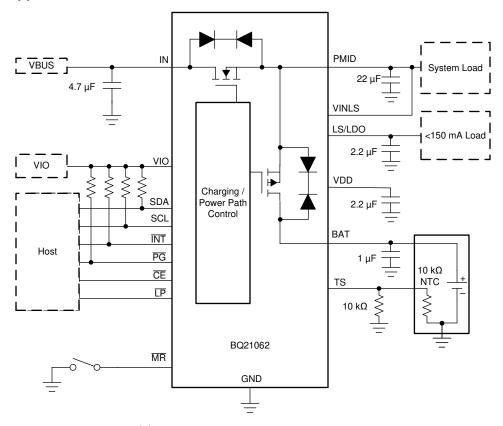


图 10-1. Typical Application Diagram



10.2.1 Design Requirements

The design parameters for the following design example are shown in the table below.

表 10-1. Design Parameters

PARAMETER	VALUE				
IN Supply Voltage	5 V				
Battery Regulation Voltage	4.35 V				
LDO Output Voltage	LDO (1.8 V)				

10.2.2 Detailed Design Procedure

10.2.2.1 Input (IN/PMID) Capacitors

Low ESR ceramic capacitors such as X7R or X5R is preferred for input decoupling capacitors and should be places as close as possible to the supply and ground pins fo the IC. Due to the voltage derating of the capacitors it is recommended at 25-V rated capacitors are used for IN and PMID pins which can normally operate at 5 V. After derating the minimum capacitance must be higher than 1 µF.

10.2.2.2 VDD, LDO Input and Output Capacitors

A Low ESR ceramic capacitor such as X7R or X5R is recommended for the LDO decoupling capacitor. A $4.7-\mu F$ capacitor is recommended for VDD output. For the LDO output a $2.2-\mu F$ capacitor is recommended. The minimum supported capacitance after derating must be higher than $1~\mu F$ to ensure stability. The VINLS input bypass capacitor value should match or exceed the LDO output capacitor value.

10.2.2.3 TS

A 10-K Ω NTC should be connected in parallel to a 10-k Ω biasing resistor connected to ground. The ground connection of both the NTC and biasing resistor must be done as close as possible to the GND pin of the device or kelvin connected to it to minimize any error in TS measurement due IR drops on the board ground lines.

If the system designer does not wish to use the TS function for charging control, a 5-k Ω resistor from TS to ground must be connected.

10.2.2.4 Recommended Passive Components

表 10-2. Recommended Passive Components

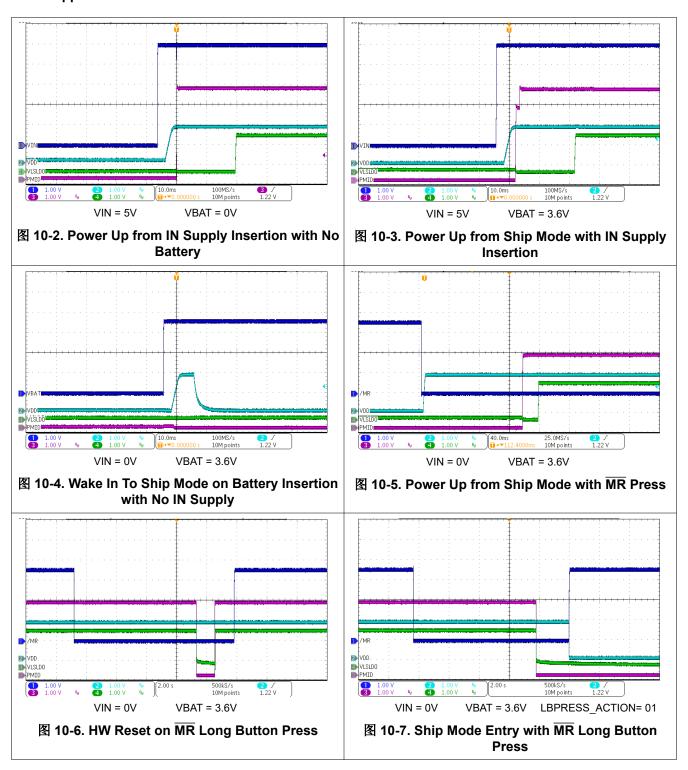
		MIN	NOM	MAX	UNIT
C _{PMID}	Capacitance in PMID pin	1 ⁽¹⁾	22	47	μF
C _{LDO}	LDO output capacitance	1	2.2	4.7	μF
C _{VDD}	VDD output capacitance	1	2.2	4.7	μF
C _{BAT}	BAT pin capacitance	1		-	μF
C _{IN}	IN input bypass capacitance	1	4.7	10	μF
C _{INLS}	VINLS input bypass capacitance	1		-	μF
C _{TS}	Capacitance from TS pin to ground	0	0	1	nF

(1) For PMID regulation loop stability, for better transient performance a minimum capacitance (after derating) of 10 μF is recommended.

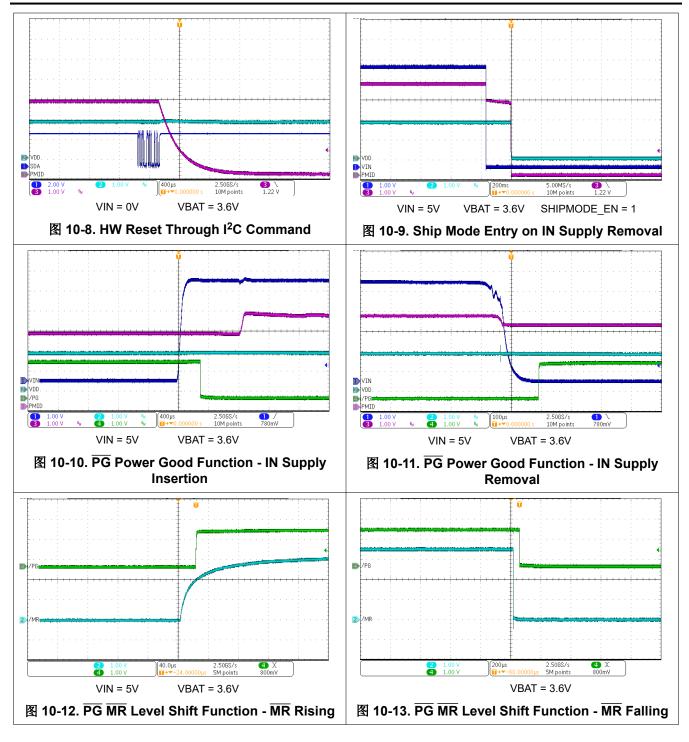
Product Folder Links: BQ21062

Copyright © 2023 Texas Instruments Incorporated

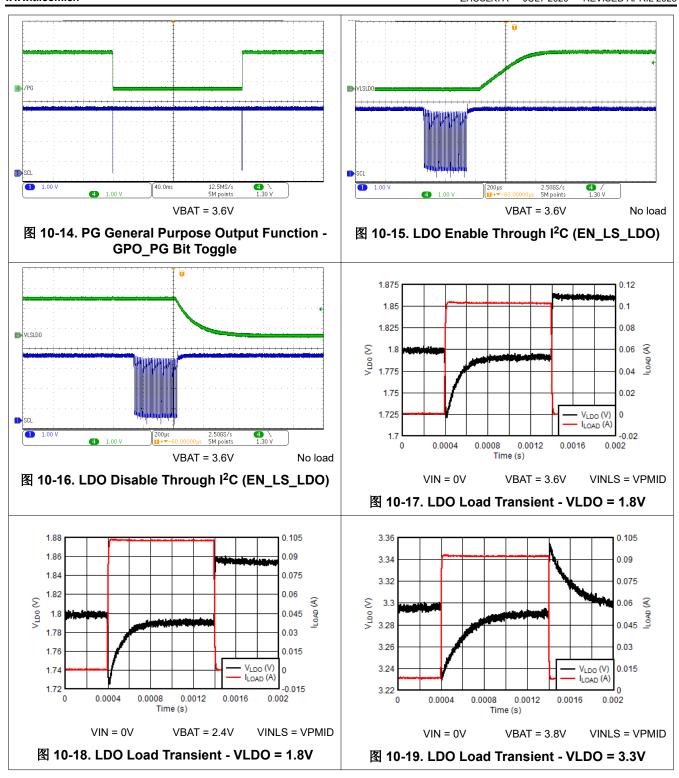
10.2.3 Application Curves





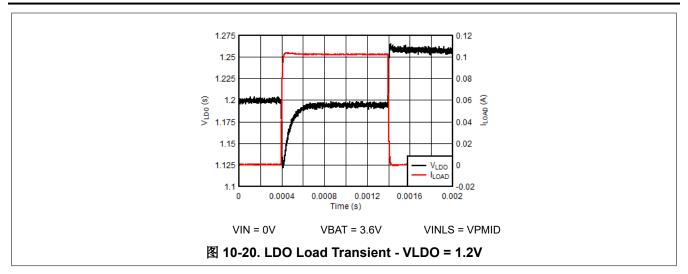






Product Folder Links: BQ21062





11 Power Supply Recommendations

The BQ21062 requires the adapter or IN supply to be between 3.4 V and 5.5 V with at least 600-mA rating. The battery voltage must be higher than 2.4 V or $V_{BATUVLO}$ to ensure proper operation.



12 Layout

12.1 Layout Guidelines

- Have solid ground plane that is tied to the GND bump
- Place LDO and VDD output capacitors as close as possible to the respective bumps and GND or ground plane with short copper trace connection
- Place PMID capacitor as close to the PMID bump as possible and GND or ground plane.

12.2 Layout Example

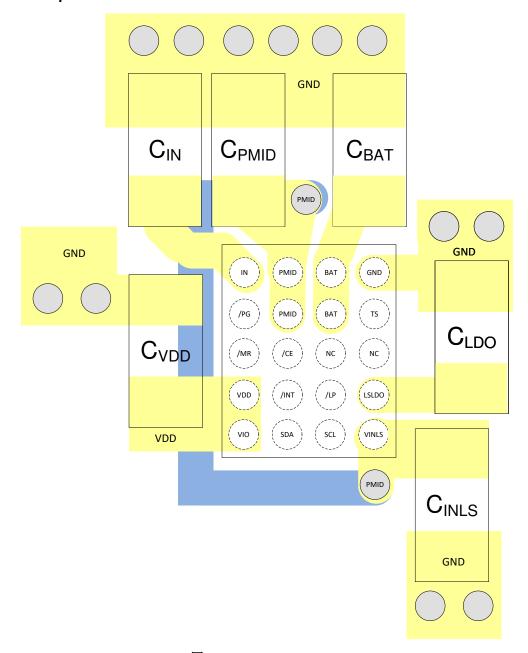


图 12-1. Layout Example

Product Folder Links: BQ21062



13 Device and Documentation Support

13.1 Device Support

13.1.1 第三方产品免责声明

TI 发布的与第三方产品或服务有关的信息,不能构成与此类产品或服务或保修的适用性有关的认可,不能构成此 类产品或服务单独或与任何 TI 产品或服务一起的表示或认可。

13.2 Documentation Support

13.2.1 Related Documentation

For related documentation see the following: BQ21061EVM User's Guide and BQ21061 Setup Guide Tool

13.3 接收文档更新通知

要接收文档更新通知,请导航至 ti.com 上的器件产品文件夹。点击*订阅更新* 进行注册,即可每周接收产品信息更 改摘要。有关更改的详细信息,请查看任何已修订文档中包含的修订历史记录。

13.4 支持资源

TI E2E™ 支持论坛是工程师的重要参考资料,可直接从专家获得快速、经过验证的解答和设计帮助。搜索现有解 答或提出自己的问题可获得所需的快速设计帮助。

链接的内容由各个贡献者"按原样"提供。这些内容并不构成 TI 技术规范,并且不一定反映 TI 的观点;请参阅 TI的《使用条款》。

13.5 Trademarks

TI E2E[™] is a trademark of Texas Instruments.

所有商标均为其各自所有者的财产。

13.6 静电放电警告



静电放电 (ESD) 会损坏这个集成电路。德州仪器 (TI) 建议通过适当的预防措施处理所有集成电路。如果不遵守正确的处理 和安装程序,可能会损坏集成电路。

ESD 的损坏小至导致微小的性能降级,大至整个器件故障。精密的集成电路可能更容易受到损坏,这是因为非常细微的参 数更改都可能会导致器件与其发布的规格不相符。

13.7 术语表

本术语表列出并解释了术语、首字母缩略词和定义。 TI 术语表

Product Folder Links: BQ21062



14 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

www.ti.com 9-Nov-2025

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
BQ21062YFPR	Active	Production	DSBGA (YFP) 20	3000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 85	BQ21062
BQ21062YFPR.A	Active	Production	DSBGA (YFP) 20	3000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 85	BQ21062

⁽¹⁾ Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

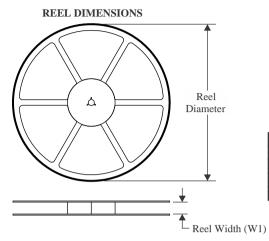
⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

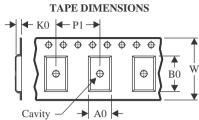
⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

PACKAGE MATERIALS INFORMATION

www.ti.com 26-Aug-2025

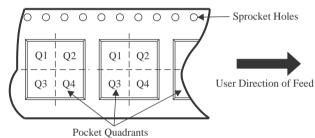
TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

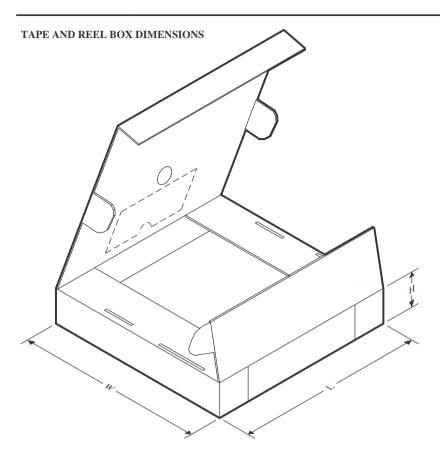


*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
BQ21062YFPR	DSBGA	YFP	20	3000	180.0	8.4	1.77	2.17	0.62	4.0	8.0	Q1

PACKAGE MATERIALS INFORMATION

www.ti.com 26-Aug-2025

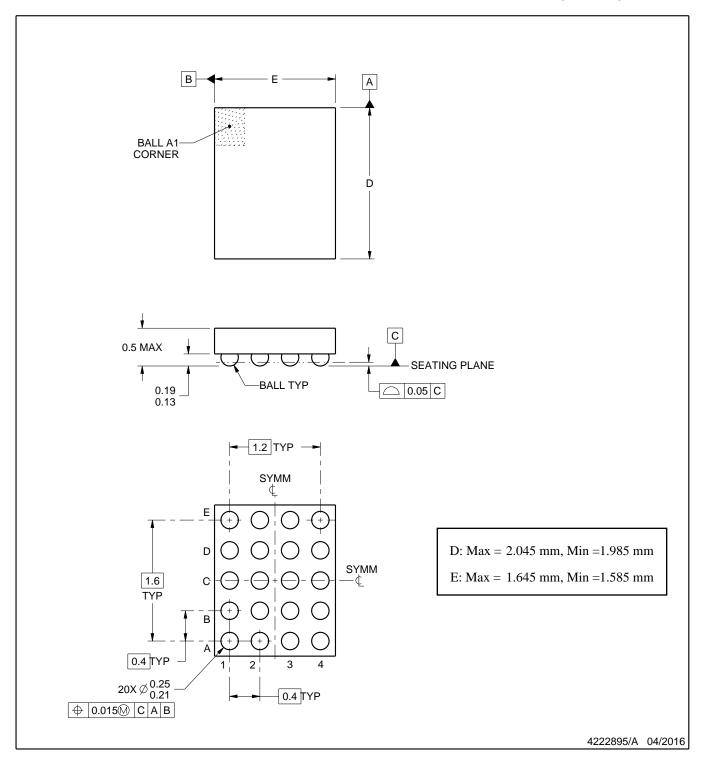


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
BQ21062YFPR	DSBGA	YFP	20	3000	182.0	182.0	20.0



DIE SIZE BALL GRID ARRAY



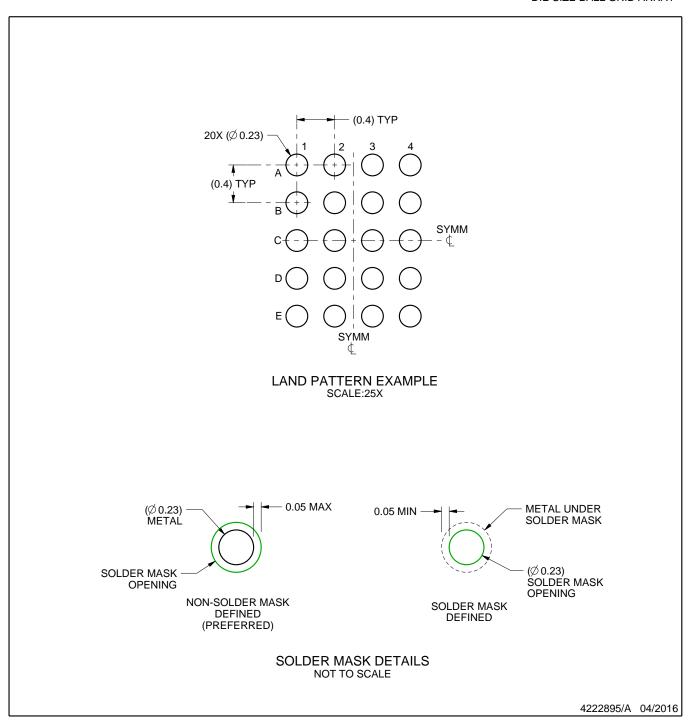
NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.



DIE SIZE BALL GRID ARRAY

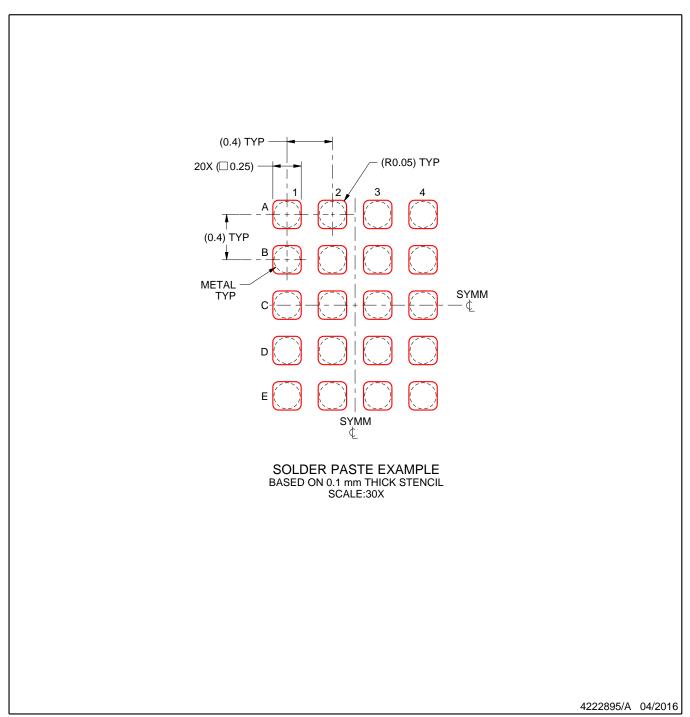


NOTES: (continued)

3. Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. For more information, see Texas Instruments literature number SNVA009 (www.ti.com/lit/snva009).



DIE SIZE BALL GRID ARRAY



NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.



重要通知和免责声明

TI"按原样"提供技术和可靠性数据(包括数据表)、设计资源(包括参考设计)、应用或其他设计建议、网络工具、安全信息和其他资源,不保证没有瑕疵且不做出任何明示或暗示的担保,包括但不限于对适销性、与某特定用途的适用性或不侵犯任何第三方知识产权的暗示担保。

这些资源可供使用 TI 产品进行设计的熟练开发人员使用。您将自行承担以下全部责任:(1) 针对您的应用选择合适的 TI 产品,(2) 设计、验证并测试您的应用,(3) 确保您的应用满足相应标准以及任何其他安全、安保法规或其他要求。

这些资源如有变更,恕不另行通知。TI 授权您仅可将这些资源用于研发本资源所述的 TI 产品的相关应用。严禁以其他方式对这些资源进行复制或展示。您无权使用任何其他 TI 知识产权或任何第三方知识产权。对于因您对这些资源的使用而对 TI 及其代表造成的任何索赔、损害、成本、损失和债务,您将全额赔偿,TI 对此概不负责。

TI 提供的产品受 TI 销售条款)、TI 通用质量指南 或 ti.com 上其他适用条款或 TI 产品随附的其他适用条款的约束。TI 提供这些资源并不会扩展或以其他方式更改 TI 针对 TI 产品发布的适用的担保或担保免责声明。 除非德州仪器 (TI) 明确将某产品指定为定制产品或客户特定产品,否则其产品均为按确定价格收入目录的标准通用器件。

TI 反对并拒绝您可能提出的任何其他或不同的条款。

版权所有 © 2025, 德州仪器 (TI) 公司

最后更新日期: 2025 年 10 月